

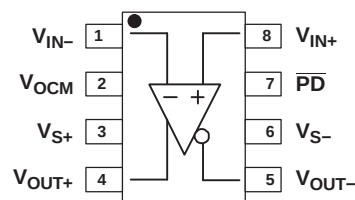
WIDEBAND, LOW-DISTORTION, FULLY DIFFERENTIAL AMPLIFIERS

FEATURES

- Fully Differential Architecture
- Bandwidth: 260 MHz
- Slew Rate: 1800 V/ μ s
- IMD_3 : -73 dBc at 30 MHz
- OIP_3 : 29 dBm at 30 MHz
- Output Common-Mode Control
- Wide Power-Supply Voltage Range: 5 V, ± 5 V, 12 V, 15 V
- Input Common-Mode Range Shifted to Include the Negative Power-Supply Rail
- Power-Down Capability (THS4504)
- Evaluation Module Available

APPLICATIONS

- High Linearity Analog-to-Digital Converter Preamplifier
- Wireless Communication Receiver Chains
- Single-Ended to Differential Conversion
- Differential Line Driver
- Active Filtering of Differential Signals



DESCRIPTION

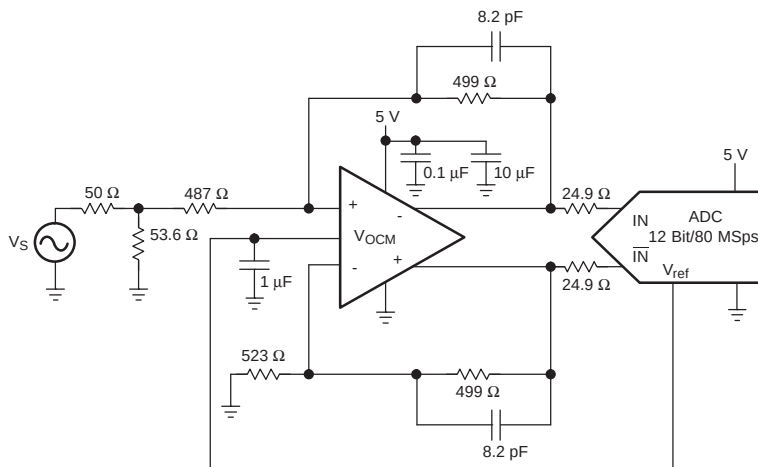
The THS4504 and THS4505 are high-performance, fully differential amplifiers from Texas Instruments. The THS4504, featuring power-down capability, and the THS4505, without power-down capability, set new performance standards for fully differential amplifiers with unsurpassed linearity, supporting 12-bit operation through 40 MHz. Package options include the SOIC-8 and the MSOP-8 with PowerPAD™ for a smaller footprint, enhanced ac performance, and improved thermal dissipation capability.

RELATED DEVICES

DEVICE ⁽¹⁾	DESCRIPTION
THS4504/5	260 MHz, 1800 V/ μ s, V_{ICR} Includes V_{S-}
THS4500/1	370 MHz, 2800 V/ μ s, V_{ICR} Includes V_{S-}
THS4502/3	370 MHz, 2800 V/ μ s, Centered V_{ICR}
THS4120/1	3.3 V, 100 MHz, 43 V/ μ s, 3.7 nV/ $\sqrt{\text{Hz}}$
THS4130/1	15 V, 150 MHz, 51 V/ μ s, 1.3 nV/ $\sqrt{\text{Hz}}$
THS4140/1	15 V, 160 MHz, 450 V/ μ s, 6.5 nV/ $\sqrt{\text{Hz}}$
THS4150/1	15 V, 150 MHz, 650 V/ μ s, 7.6 nV/ $\sqrt{\text{Hz}}$

(1) Even numbered devices feature power-down capability

APPLICATION CIRCUIT DIAGRAM



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments, Incorporated.
All other trademarks are the property of their respective owners.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range, unless otherwise noted.

	UNIT
Supply voltage, V_S	16.5 V
Input voltage, V_I	$\pm V_S$
Output current, I_O	150 mA
Differential input voltage, V_{ID}	4 V
Continuous power dissipation	See Package Dissipation Ratings table
Maximum junction temperature, T_J	+150°C
Maximum junction temperature, continuous operation, long-term reliability, T_J ⁽²⁾	+125°C
Storage temperature range, T_{stg}	–65°C to +150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	+300°C

- (1) The absolute maximum ratings under any condition is limited by the constraints of the silicon process. Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.

PACKAGE DISSIPATION RATINGS

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W) ⁽¹⁾	POWER RATING ⁽²⁾	
			$T_A \leq +25^\circ\text{C}$	$T_A = +85^\circ\text{C}$
D (8-pin)	38.3	97.5	1.02 W	410 mW
DGN (8-pin)	4.7	58.4	1.71 W	685 mW
DGK (8-pin)	54.2	260	385 mW	154 mW

- (1) This data was taken using the JEDEC standard High-K test PCB.
- (2) Power rating is determined with a junction temperature of +125°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below +125°C for best performance and long term reliability.

RECOMMENDED OPERATING CONDITIONS

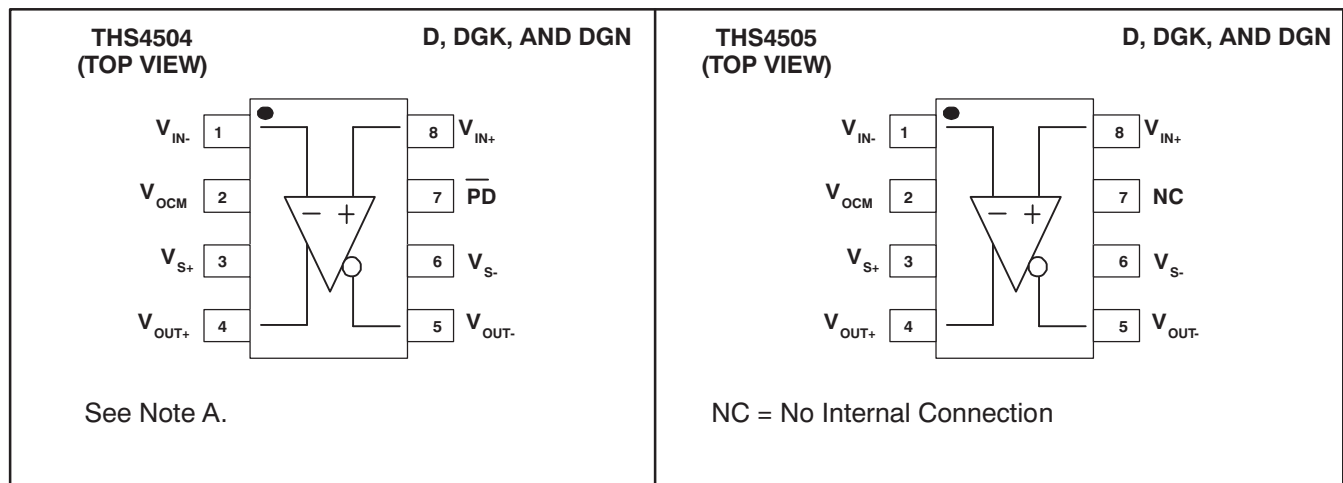
		MIN	NOM	MAX	UNIT
Supply voltage	Dual supply		± 5	± 7.5	V
	Single supply	4.5	5	15	
Operating free-air temperature, T_A		–40		+85	°C

ORDERING INFORMATION⁽¹⁾

PACKAGED DEVICES	PACKAGE TYPE	PACKAGE MARKINGS	TRANSPORT MEDIA, QUANTITY
Power-down			
THS4504D	SOIC-8	—	Rails, 75
THS4504DR			Tape and Reel, 2500
THS4504DGK	MSOP-8	ASZ	Rails, 100
THS4504DGKR			Tape and Reel, 2500
THS4504DGN	MSOP-8-PP ⁽²⁾	BDB	Rails, 80
THS4504DGNR			Tape and Reel, 2500
Non-power-down			
THS4505D	SOIC-8	—	Rails, 75
THS4505DR			Tape and Reel, 2500
THS4505DGK	MSOP-8	ATA	Rails, 100
THS4505DGKR			Tape and Reel, 2500
THS4505DGN	MSOP-8-PP ⁽²⁾	BDC	Rails, 80
THS4505DGNR			Tape and Reel, 2500

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) The PowerPAD is electrically isolated from all other pins.

PIN ASSIGNMENTS



A. The devices with the power-down option default to the ON state if no signal is applied to the $\overline{\text{PD}}$ pin.

ELECTRICAL CHARACTERISTICS: $V_S = \pm 5\text{ V}$

$V_S = \pm 5\text{ V}$, $R_F = R_G = 499\ \Omega$, $R_L = 800\ \Omega$, $G = +1$, and single-ended input, unless otherwise noted.

PARAMETER	TEST CONDITIONS	THS4504 AND THS4505					
		TYP	OVER TEMPERATURE				MIN/ TYP/ MAX
		+25°C	+25°C	0°C to +70°C	−40°C to +85°C	UNIT	
AC PERFORMANCE							
Small-signal bandwidth	G = 1, P _{IN} = −20 dBm, R _F = 499 Ω	260				MHz	Typ
	G = 2, P _{IN} = −20 dBm, R _F = 499 Ω	110				MHz	Typ
	G = 5, P _{IN} = −20 dBm, R _F = 499 Ω	40				MHz	Typ
	G = 10, P _{IN} = −20 dBm, R _F = 499 Ω	20				MHz	Typ
Gain-bandwidth product	G > +10	210				MHz	Typ
Bandwidth for 0.1-dB flatness	P _{IN} = −20 dBm	65				MHz	Typ
Large-signal bandwidth	G = 1, V _P = 2 V	250				MHz	Typ
Slew rate	4 V _{PP} Step	1800				V/μs	Typ
Rise time	2 V _{PP} Step	0.8				ns	Typ
Fall time	2 V _{PP} Step	1				ns	Typ
Settling time to 0.01%	V _O = 4 V _{PP}	100				ns	Typ
0.1%	V _O = 4 V _{PP}	20				ns	Typ
Harmonic distortion	G = 1, V _O = 2 V _{PP}						Typ
2nd harmonic	f = 8 MHz	−79				dBc	Typ
	f = 30 MHz	−66				dBc	Typ
3rd harmonic	f = 8 MHz	−93				dBc	Typ
	f = 30 MHz	−65				dBc	Typ
Third-order intermodulation distortion	V _O = 2 V _{PP} , f _C = 30 MHz, R _F = 499 Ω, 200 kHz tone spacing	−73				dBc	Typ
Third-order output intercept point	f _C = 30 MHz, R _f = 499 Ω, Referenced to 50 Ω	29				dBm	Typ
Input voltage noise	f > 1 MHz	8				nV/√Hz	Typ
Input current noise	f > 100 kHz	2				pA/√Hz	Typ
Overdrive recovery time	Overdrive = 5.5 V	60				ns	Typ
DC PERFORMANCE							
Open-loop voltage gain		55	52	50	50	dB	Min
Input offset voltage		−4	−7/−1	−8/0	−9/+1	mV	Max
Average offset voltage drift				±10	±10	μV/°C	Typ
Input bias current		4	4.6	5	5.2	μA	Max
Average bias current drift				±10	±10	nA/°C	Typ
Input offset current		0.5	1	2	2	μA	Max
Average offset current drift				±40	±40	nA/°C	Typ

ELECTRICAL CHARACTERISTICS: $V_S = \pm 5\text{ V}$ (continued)
 $V_S = \pm 5\text{ V}$, $R_F = R_G = 499\ \Omega$, $R_L = 800\ \Omega$, $G = +1$, and single-ended input, unless otherwise noted.

PARAMETER	TEST CONDITIONS	THS4504 AND THS4505					
		TYP	OVER TEMPERATURE				MIN/ TYP/ MAX
		+25°C	+25°C	0°C to +70°C	–40°C to +85°C	UNIT	
INPUT							
Common-mode input range		–5.7/2.6	–5.4/2.3	–5.1/2	–5.1/2	V	Min
Common-mode rejection ratio		80	74	70	70	dB	Min
Input impedance		10 ⁷ 1				Ω pF	Typ
OUTPUT							
Differential output voltage swing	R _L = 1 kΩ	±8	±7.6	±7.4	±7.4	V	Min
Differential output current drive	R _L = 20 Ω	130	110	100	100	mA	Min
Output balance error	P _{IN} = –20 dBm, f = 100 kHz	–65				dB	Typ
Closed-loop output impedance (single-ended)	f = 1 MHz	0.1				Ω	Typ
OUTPUT COMMON-MODE VOLTAGE CONTROL							
Small-signal bandwidth	R _L = 400 Ω	200				MHz	Typ
Slew rate	2 V _{PP} Step	92				V/μs	Typ
Minimum gain		1	0.98	0.98	0.98	V/V	Min
Maximum gain		1	1.02	1.02	1.02	V/V	Max
Common-mode offset voltage		–0.4	–4.6/+3.8	–6.6/+5.8	–7.6/+6.8	mV	Max
Input bias current	V _{OCM} = 2.5 V	100	150	170	170	μA	Max
Input voltage range		±4	±3.7	±3.4	±3.4	V	Min
Input impedance		25 1				kΩ pF	Typ
Maximum default voltage	V _{OCM} left floating	0	0.05	0.10	0.10	V	Max
Minimum default voltage	V _{OCM} left floating	0	–0.05	–0.10	–0.10	V	Min
POWER SUPPLY							
Specified operating voltage		±5	±7.5	±7.5	±7.5	V	Max
Maximum quiescent current		16	20	23	25	mA	Max
Minimum quiescent current		16	13	11	9	mA	Min
Power-supply rejection (±PSRR)		80	76	73	70	dB	Min
POWER-DOWN (THS4504 ONLY)							
Enable voltage threshold	Device enabled <i>ON</i> above –2.9 V		–2.9			V	Min
Disable voltage threshold	Device disabled <i>OFF</i> below –4.3 V		–4.3			V	Max
Power-down quiescent current		800	1000	1200	1200	μA	Max
Input bias current		200	240	260	260	μA	Max
Input impedance		50 1				kΩ pF	Typ
Turn-on time delay		1000				ns	Typ
Turn-off time delay		800				ns	Typ

ELECTRICAL CHARACTERISTICS: $V_S = 5\text{ V}$

$V_S = 5\text{ V}$, $R_F = R_G = 499\ \Omega$, $R_L = 800\ \Omega$, $G = +1$, and single-ended input, unless otherwise noted.

PARAMETER	TEST CONDITIONS	THS4504 AND THS4505					
		TYP	OVER TEMPERATURE				MIN/TYP/ MAX
		+25°C	+25°C	0°C to +70°C	–40°C to +85°C	UNIT	
AC PERFORMANCE							
Small-signal bandwidth	G = 1, P _{IN} = –20 dBm, R _F = 499 Ω	210				MHz	Typ
	G = 2, P _{IN} = –20 dBm, R _F = 499 Ω	120				MHz	Typ
	G = 5, P _{IN} = –20 dBm, R _F = 499 Ω	40				MHz	Typ
	G = 10, P _{IN} = –20 dBm, R _F = 499 Ω	20				MHz	Typ
Gain-bandwidth product	G > +10	200				MHz	Typ
Bandwidth for 0.1-dB flatness	P _{IN} = –20 dBm	100				MHz	Typ
Large-signal bandwidth	G = 1, V _P = 1 V	200				MHz	Typ
Slew rate	2 V _{PP} Step	900				V/μs	Typ
Rise time	2 V _{PP} Step	1.1				ns	Typ
Fall time	2 V _{PP} Step	1				ns	Typ
Settling time to 0.01%	V _O = 2 V Step	100				ns	Typ
0.1%	V _O = 2 V Step	20				ns	Typ
Harmonic distortion	G = 1, V _O = 2 V _{PP}						Typ
2nd harmonic	f = 8 MHz,	–77				dBc	Typ
	f = 30 MHz	–56				dBc	Typ
3rd harmonic	f = 8 MHz	–74				dBc	Typ
	f = 30 MHz	–57				dBc	Typ
Third-order intermodulation distortion	V _O = 2 V _{PP} , f _C = 30 MHz, R _F = 499 Ω, 200 kHz tone spacing	–72				dBc	Typ
Third-order output intercept point	f _C = 30 MHz, R _F = 499 Ω, Referenced to 50 Ω	28				dBm	Typ
Input voltage noise	f > 1 MHz	8				nV/√Hz	Typ
Input current noise	f > 100 kHz	2				pA/√Hz	Typ
Overdrive recovery time	Overdrive = 5.5 V	60				ns	Typ
DC PERFORMANCE							
Open-loop voltage gain		54	51	49	49	dB	Min
Input offset voltage		–4	–7/–1	–8/0	–9/+1	mV	Max
Average offset voltage drift				±10	±10	μV/°C	Typ
Input bias current		4	4.6	5	5.2	μA	Max
Average bias current drift				±10	±10	nA/°C	Typ
Input offset current		0.5	0.7	1.2	1.2	μA	Max
Average offset current drift				±20	±20	nA/°C	Typ

ELECTRICAL CHARACTERISTICS: $V_S = 5\text{ V}$ (continued)
 $V_S = 5\text{ V}$, $R_F = R_G = 499\ \Omega$, $R_L = 800\ \Omega$, $G = +1$, and single-ended input, unless otherwise noted.

PARAMETER	TEST CONDITIONS	THS4504 AND THS4505					
		TYP	OVER TEMPERATURE				MIN/TYP/ MAX
		+25°C	+25°C	0°C to +70°C	–40°C to +85°C	UNIT	
INPUT							
Common-mode input range		–0.7/2.6	–0.4/2.3	–0.1/2	–0.1/2	V	Min
Common-mode rejection ratio		80	74	70	70	dB	Min
Input impedance		10 ⁷ 1				Ω pF	Typ
OUTPUT							
Differential output voltage swing	R _L = 1 kΩ, Referenced to 2.5 V	±3.3	±3	±2.8	±2.8	V	Min
Output current drive	R _L = 20 Ω	110	90	80	80	mA	Min
Output balance error	P _{IN} = –20 dBm, f = 100 kHz	–38				dB	Typ
Closed-loop output impedance (single-ended)	f = 1 MHz	0.1				Ω	Typ
OUTPUT COMMON-MODE VOLTAGE CONTROL							
Small-signal bandwidth	R _L = 400 Ω	160				MHz	Typ
Slew rate	2 V _{PP} Step	80				V/μs	Typ
Minimum gain		1	0.98	0.98	0.98	V/V	Min
Maximum gain		1	1.02	1.02	1.02	V/V	Max
Common-mode offset voltage		0.4	–2.6/3.4	–4.2/5.4	–5.6/6.4	mV	Max
Input bias current	V _{OCM} = 2.5 V	1	2	3	3	μA	Max
Input voltage range		1/4	1.2/3.8	1.3/3.7	1.3/3.7	V	Min
Input impedance		25 1				kΩ pF	Typ
Maximum default voltage	V _{OCM} left floating	2.5	2.55	2.6	2.6	V	Max
Minimum default voltage	V _{OCM} left floating	2.5	2.45	2.4	2.4	V	Min
POWER SUPPLY							
Specified operating voltage		5	15	15	15	V	Max
Maximum quiescent current		14	17	19	21	mA	Max
Minimum quiescent current		14	11	10	8	mA	Min
Power-supply rejection (+PSRR)		75	72	69	66	dB	Min
POWER-DOWN (THS4504 ONLY)							
Enable voltage threshold	Device enabled <i>ON</i> above 2.1 V		2.1			V	Min
Disable voltage threshold	Device disabled <i>OFF</i> below 0.7 V		0.7			V	Max
Power-down quiescent current		600	800	1200	1200	μA	Max
Input bias current		100	125	140	140	μA	Max
Input impedance		50 1				kΩ pF	Typ
Turn-on time delay		1000				ns	Typ
Turn-off time delay		800				ns	Typ

TYPICAL CHARACTERISTICS

Table of Graphs (± 5 V)

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Small-signal frequency response	2
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Harmonic distortion (single-ended and differential input to differential output) vs Output common-mode voltage	30
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Output offset voltage at V_{OCM} vs Output common-mode voltage	32
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Table of Graphs (5 V)

	FIGURE
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Small-signal frequency response	39
0.1-dB gain flatness frequency response	40
Large signal frequency response	41
Harmonic distortion (single-ended input to differential output) vs Frequency	42
Harmonic distortion (single-ended input to differential output) vs Output voltage swing	43, 44
Harmonic distortion (single-ended input to differential output) vs Load resistance	45
Third-order intermodulation distortion vs Frequency	46
Third-order intercept point vs Frequency	47
Slew rate vs Differential output voltage step	48
Settling time	49, 50
Overdrive recovery	51, 52
Large-signal transient response	53
Small-signal transient response	54
Voltage and current noise vs Frequency	55
Rejection ratios vs Frequency	56
Rejection ratios vs Case temperature	57
Output balance error vs Frequency	58
Open-loop gain and phase vs Frequency	59
Open-loop gain vs Case temperature	60
Input bias offset current vs Case temperature	61
Quiescent current vs Supply voltage	62
Input offset voltage vs Case temperature	63
Common-mode rejection ratio vs Input common-mode range	64
Output voltage vs Load resistance	65
Closed-loop output impedance vs Frequency	66
Harmonic distortion (single-ended and differential input) vs Output common-mode voltage	67
Small-signal frequency response at V_{OCM}	68
Output offset voltage vs Output common-mode voltage	69
Quiescent current vs Power-down voltage	70
Turn-on and turn-off delay times	71
Single-ended output impedance in power-down vs Frequency	72
Power-down quiescent current vs Case temperature	73
Power-down quiescent current vs Supply voltage	74

TYPICAL CHARACTERISTICS: ± 5 V

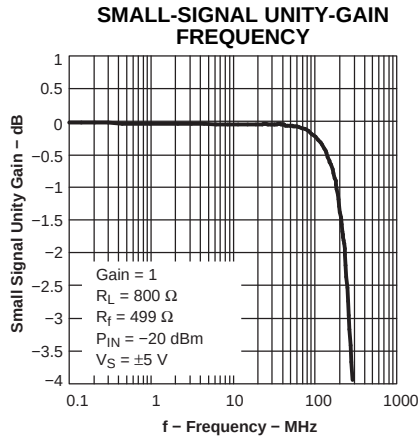


Figure 1.

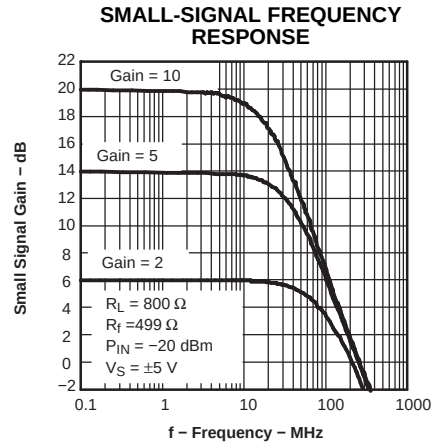


Figure 2.

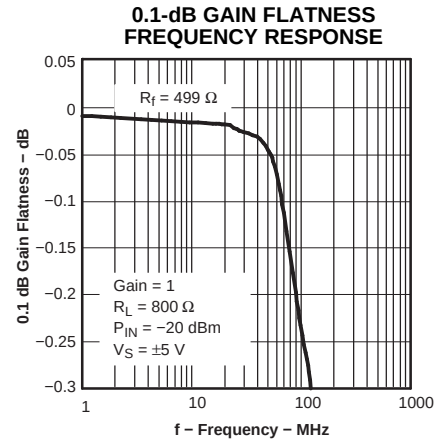


Figure 3.

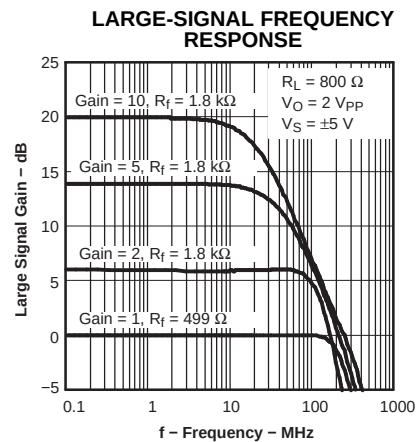


Figure 4.

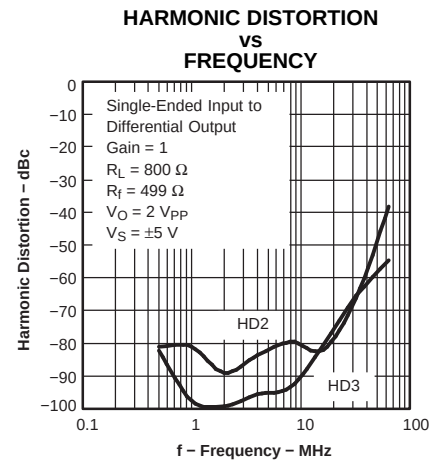


Figure 5.

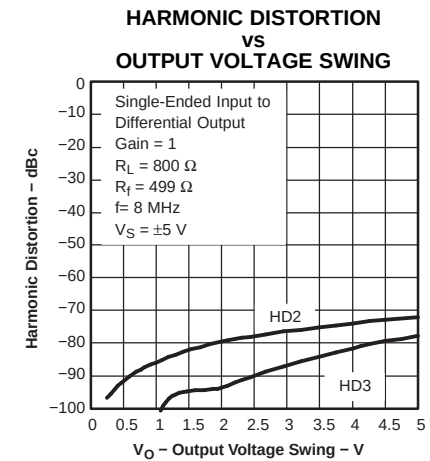


Figure 6.

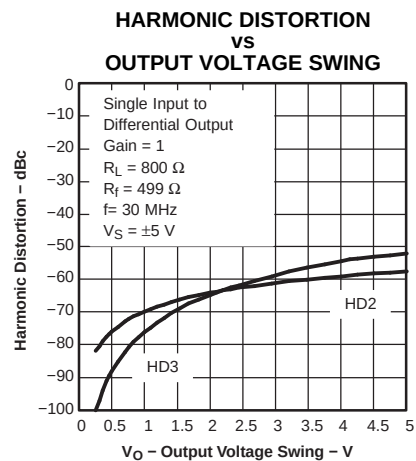


Figure 7.

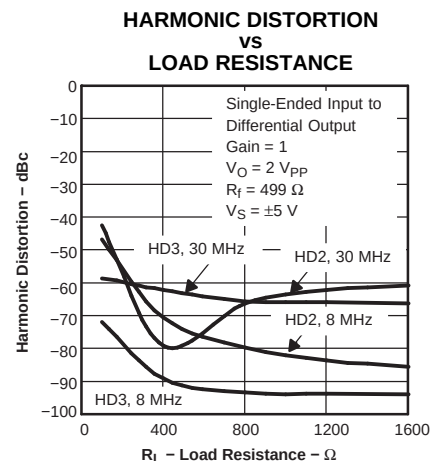


Figure 8.

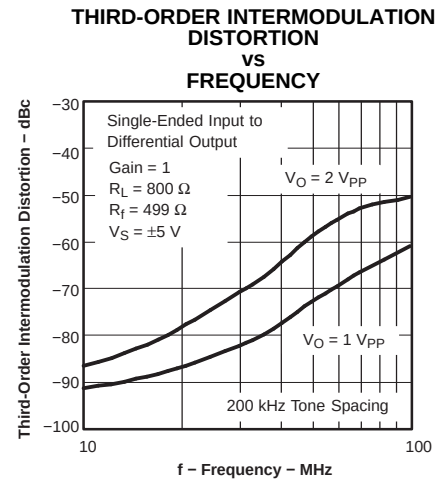


Figure 9.

TYPICAL CHARACTERISTICS: ± 5 V (continued)

**THIRD-ORDER OUTPUT INTERCEPT
POINT
VS
FREQUENCY**

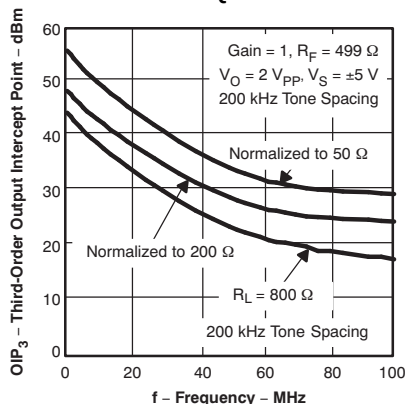


Figure 10.

**SLEW RATE
VS
DIFFERENTIAL OUTPUT VOLTAGE
STEP**

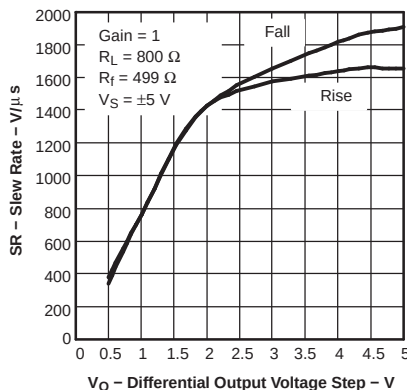


Figure 11.

SETTLING TIME

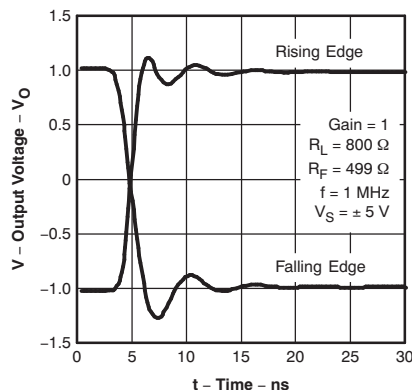


Figure 12.

SETTLING TIME

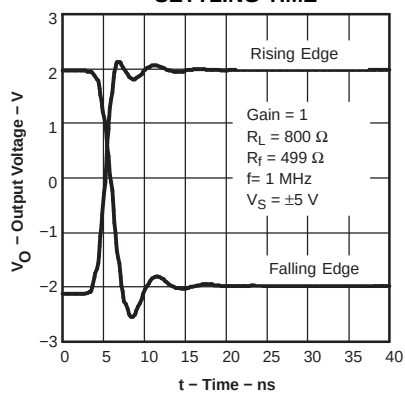


Figure 13.

**LARGE-SIGNAL TRANSIENT
RESPONSE**

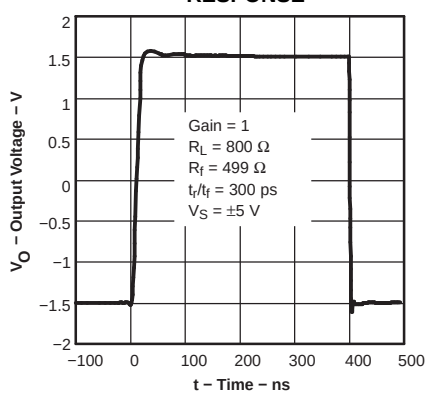


Figure 14.

**SMALL-SIGNAL TRANSIENT
RESPONSE**

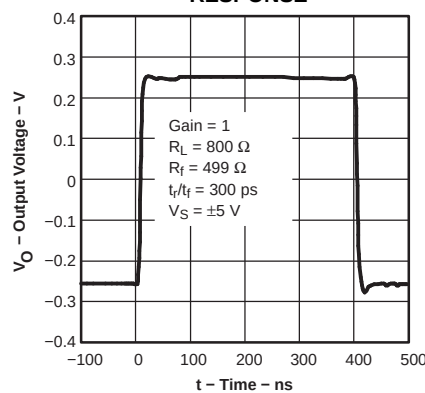


Figure 15.

OVERDRIVE RECOVERY

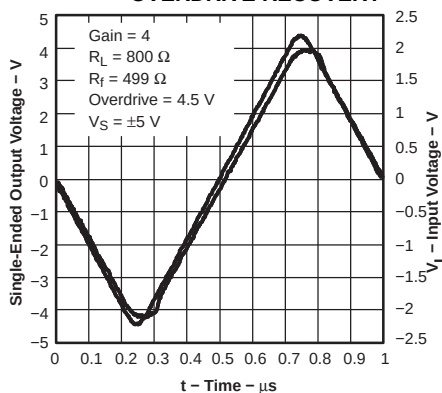


Figure 16.

OVERDRIVE RECOVERY

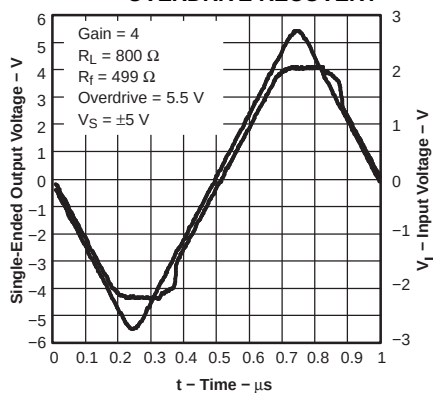


Figure 17.

**VOLTAGE AND CURRENT NOISE
VS
FREQUENCY**

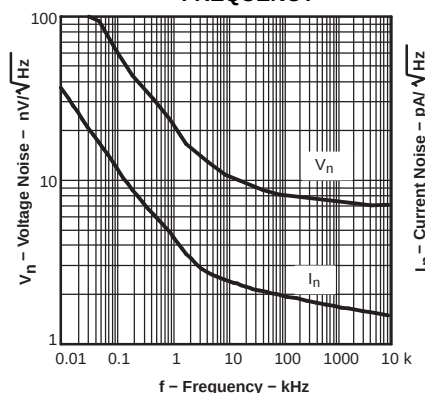


Figure 18.

TYPICAL CHARACTERISTICS: ± 5 V (continued)

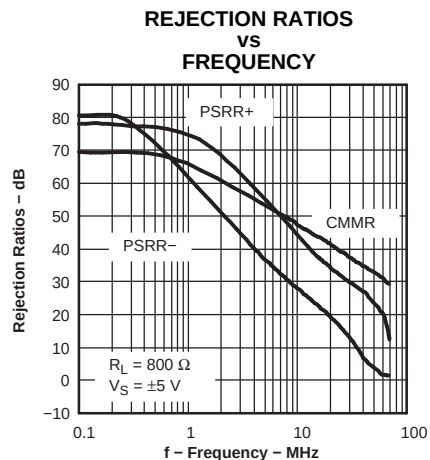


Figure 19.

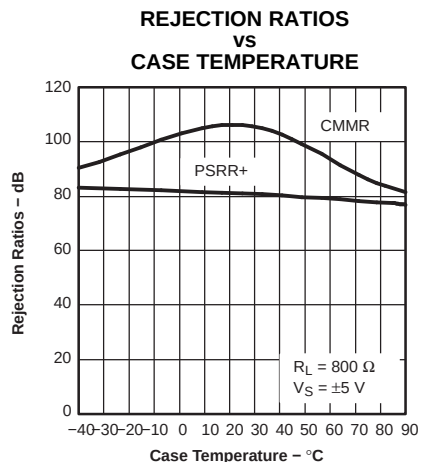


Figure 20.

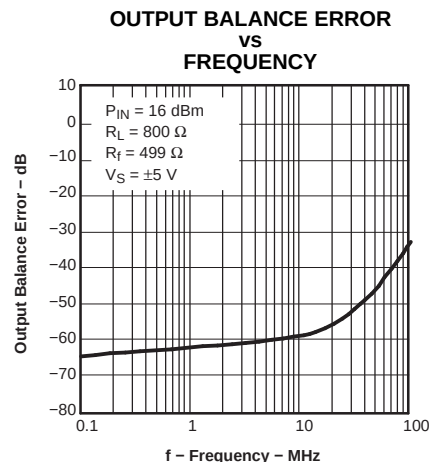


Figure 21.

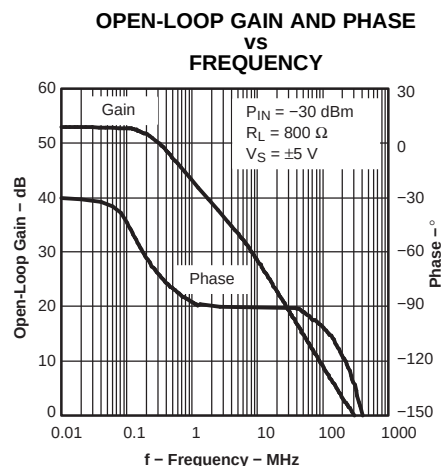


Figure 22.

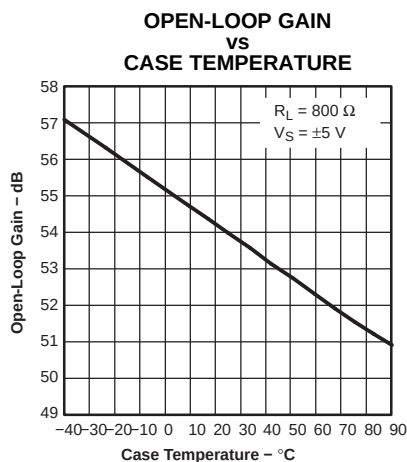


Figure 23.

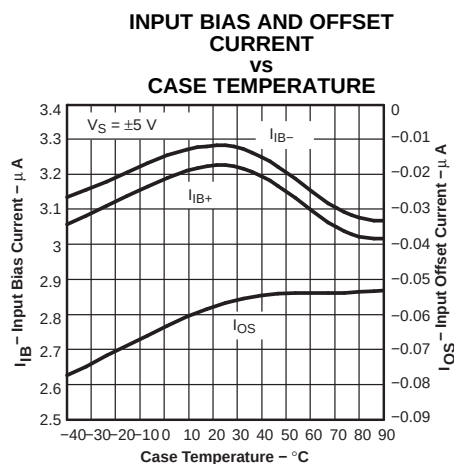


Figure 24.

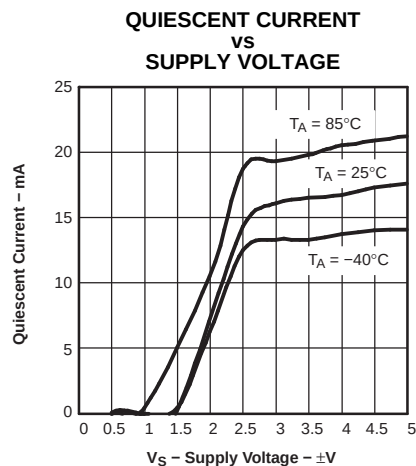


Figure 25.

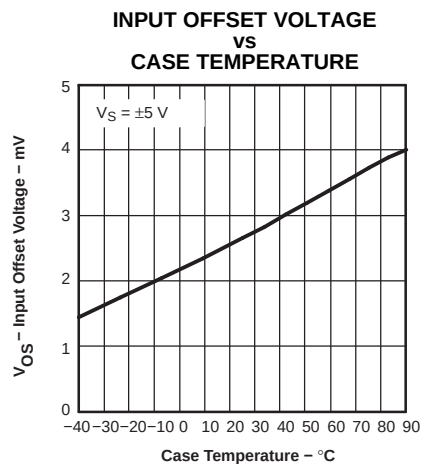


Figure 26.

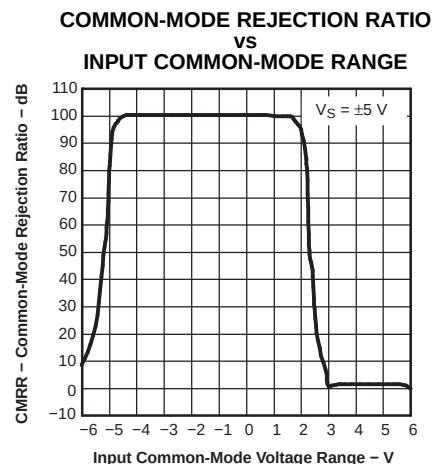


Figure 27.

TYPICAL CHARACTERISTICS: ± 5 V (continued)

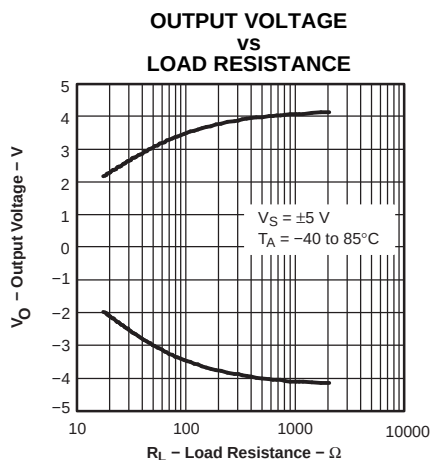


Figure 28.

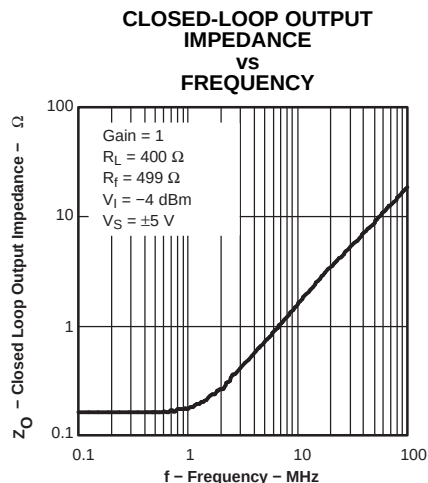


Figure 29.

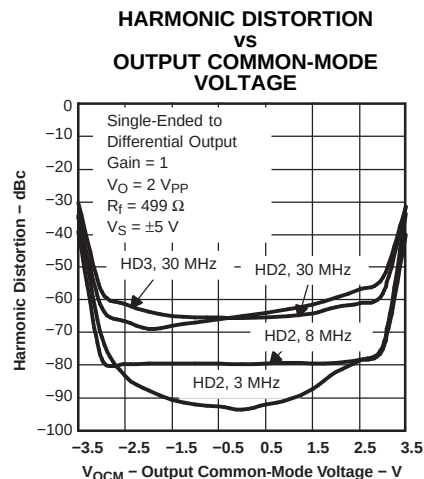


Figure 30.

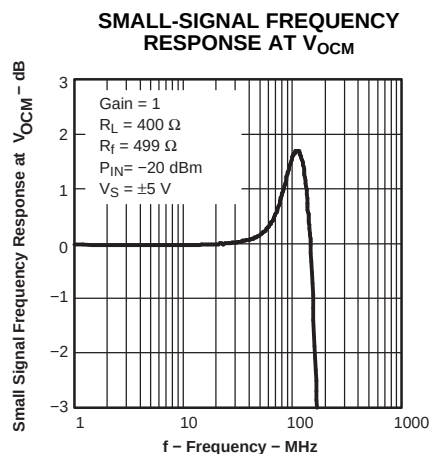


Figure 31.

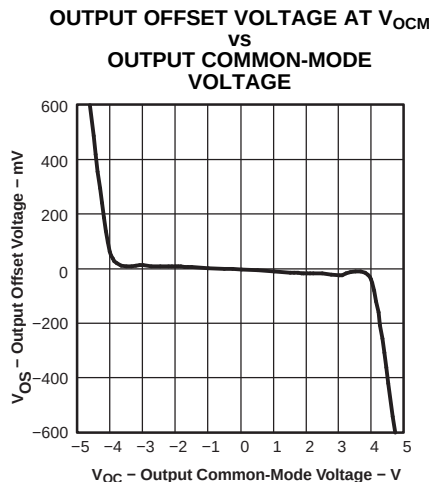


Figure 32.

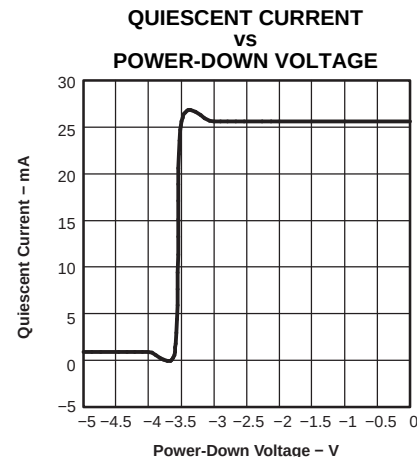


Figure 33.

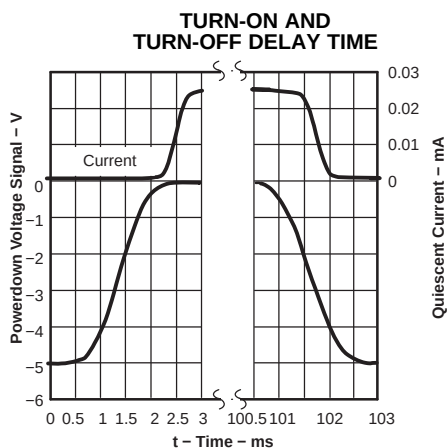


Figure 34.

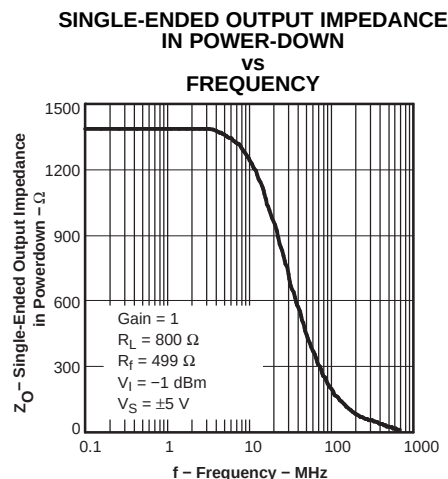


Figure 35.

TYPICAL CHARACTERISTICS: ± 5 V (continued)

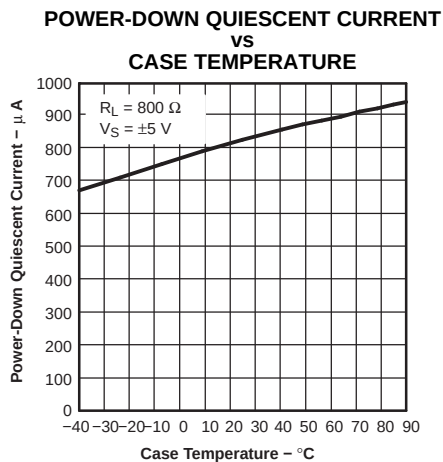


Figure 36.

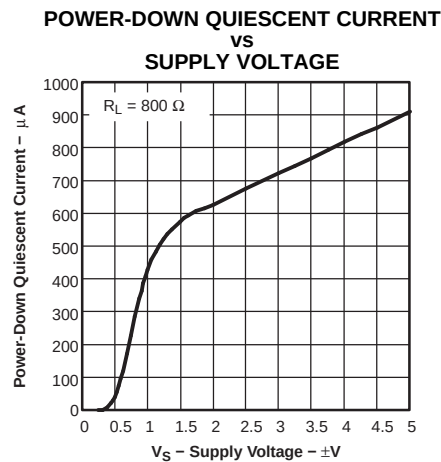


Figure 37.

TYPICAL CHARACTERISTICS: 5 V

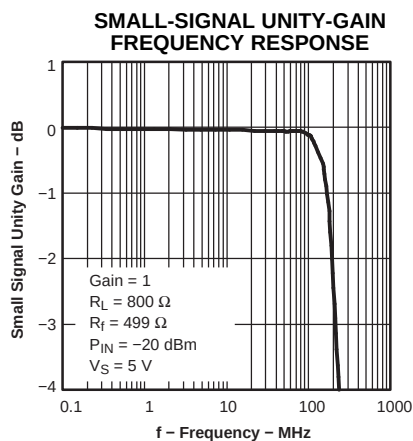


Figure 38.

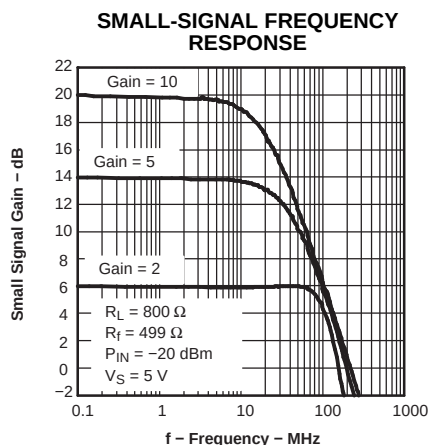


Figure 39.

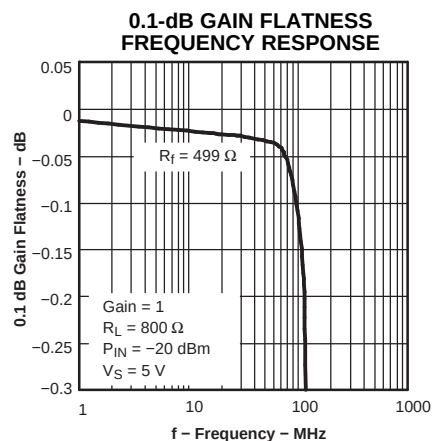


Figure 40.

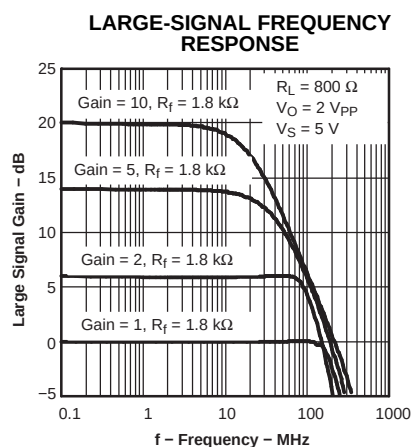


Figure 41.

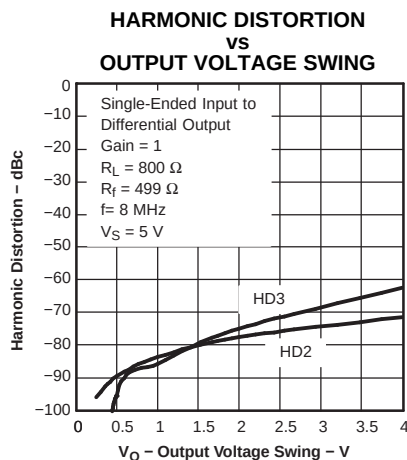


Figure 42.

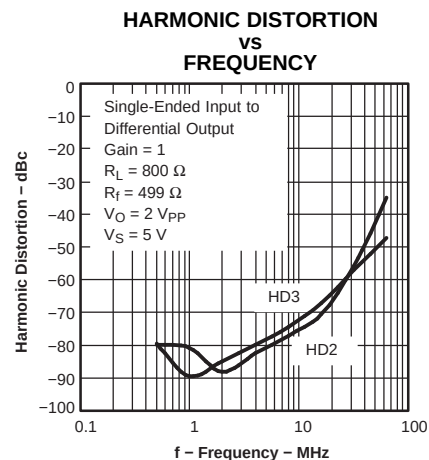


Figure 43.

TYPICAL CHARACTERISTICS: 5 V (continued)

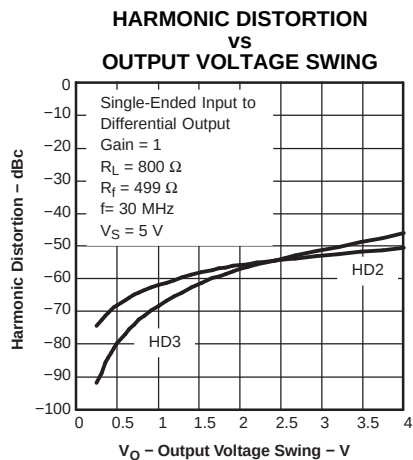


Figure 44.

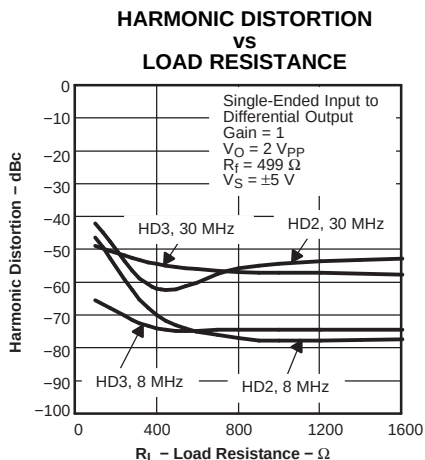


Figure 45.

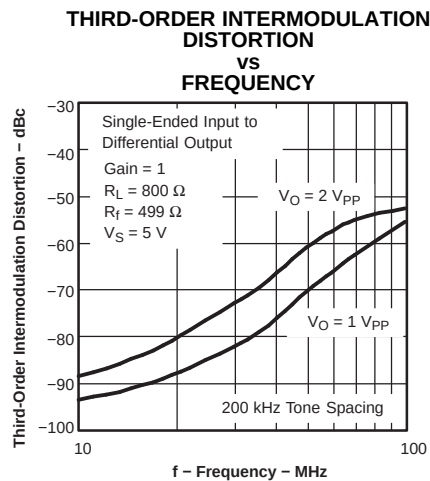


Figure 46.

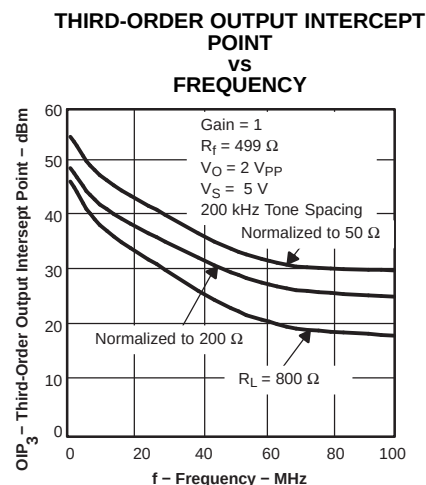


Figure 47.

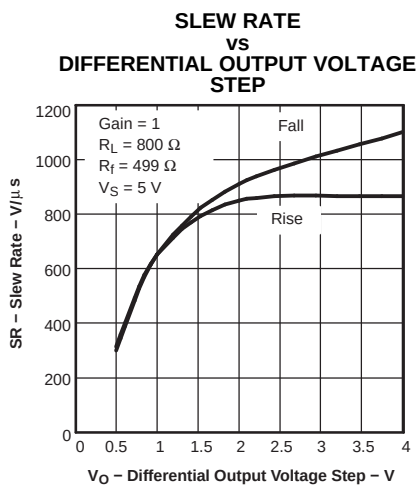


Figure 48.

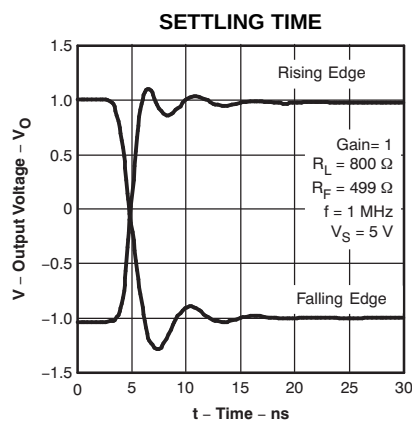


Figure 49.

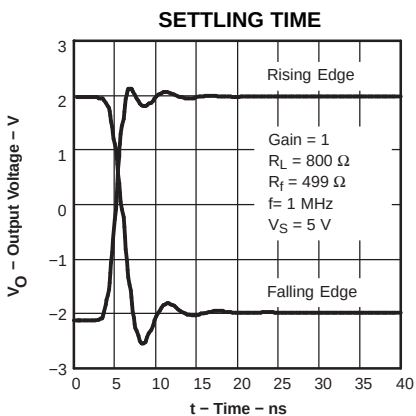


Figure 50.

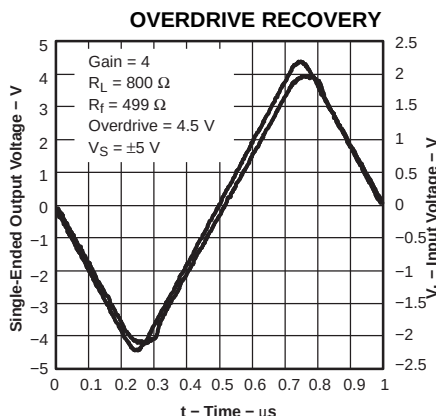


Figure 51.

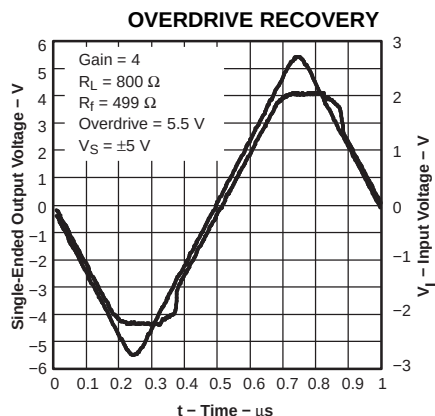


Figure 52.

TYPICAL CHARACTERISTICS: 5 V (continued)

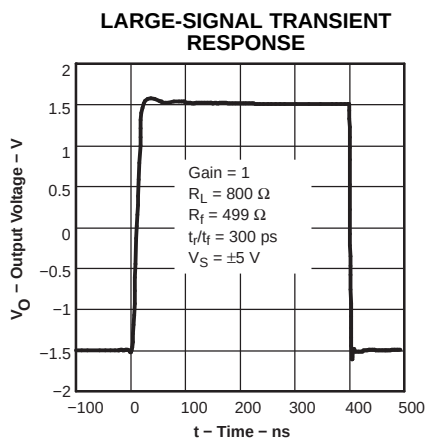


Figure 53.

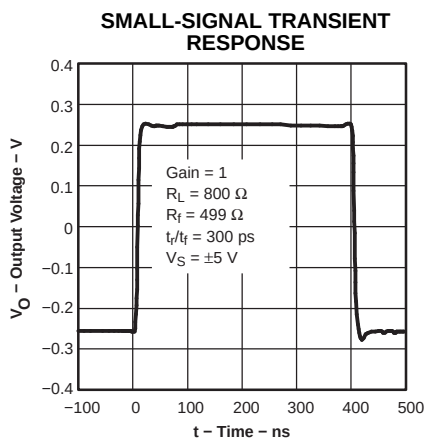


Figure 54.

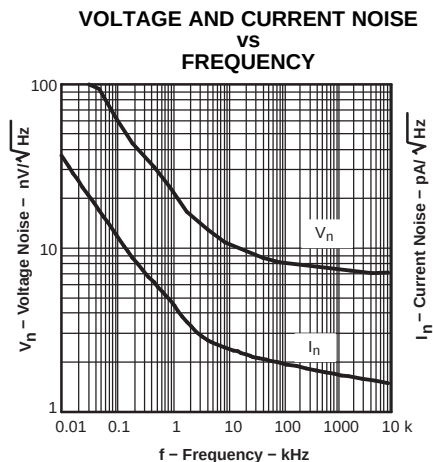


Figure 55.

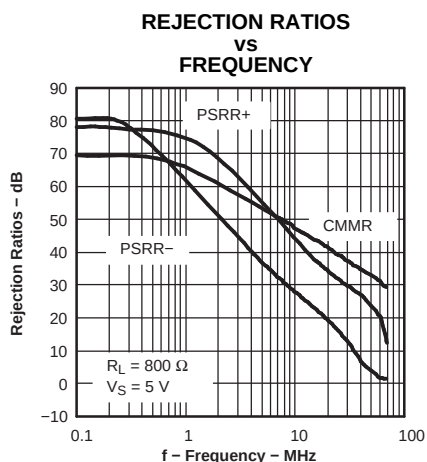


Figure 56.

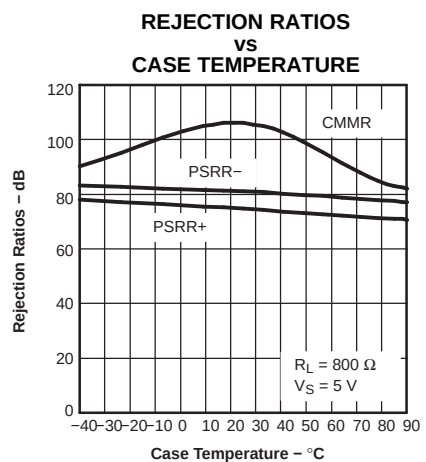


Figure 57.

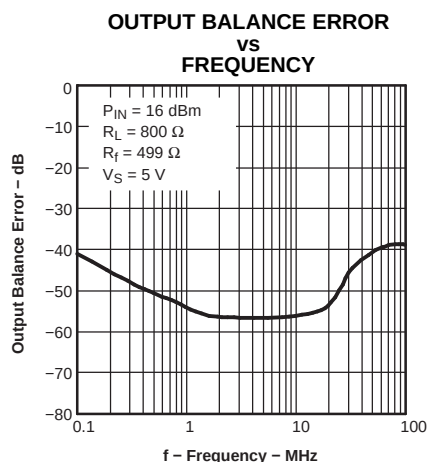


Figure 58.

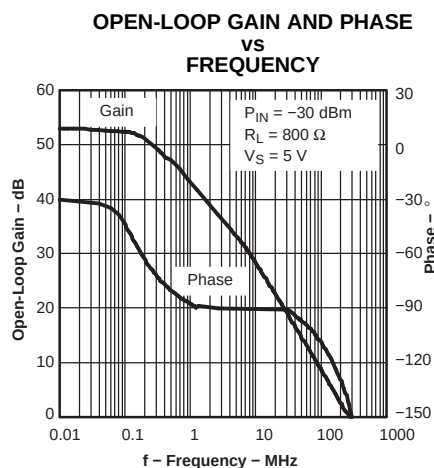


Figure 59.

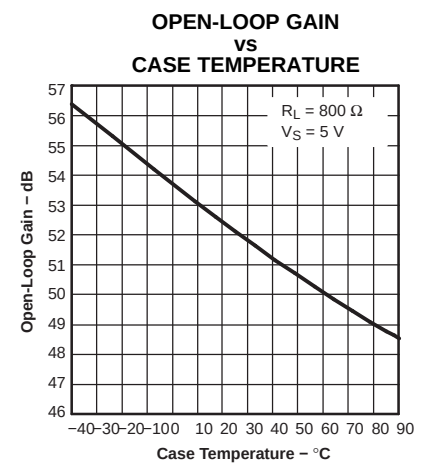


Figure 60.

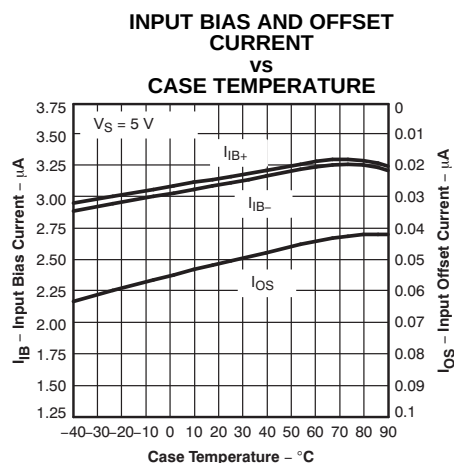
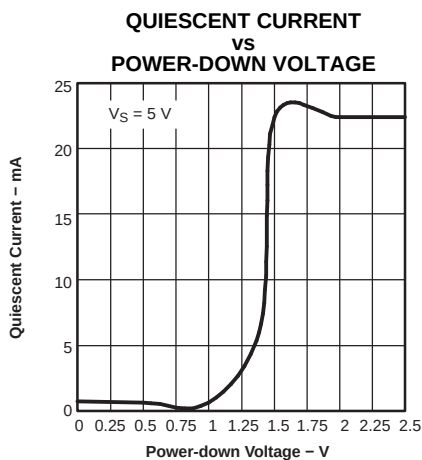
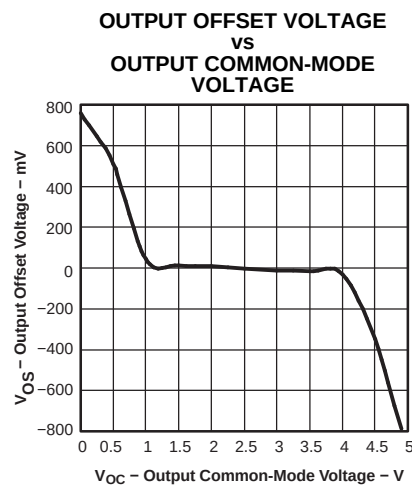
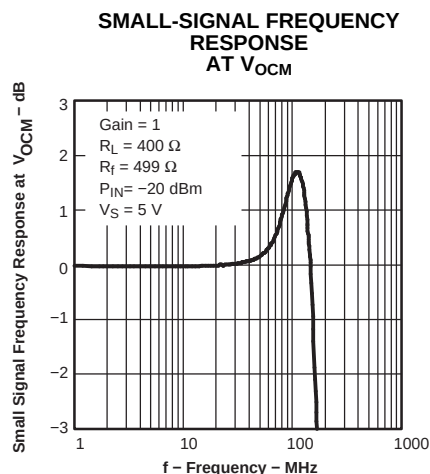
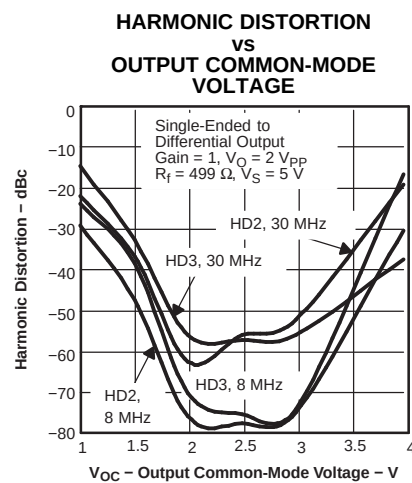
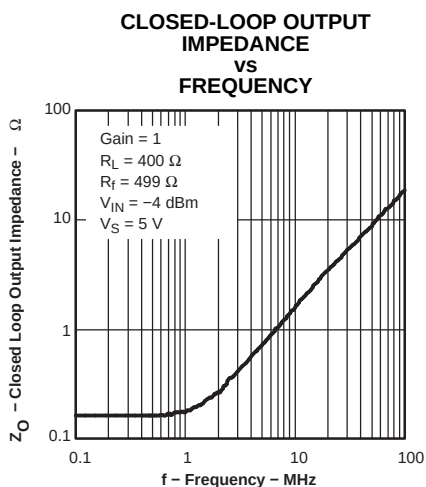
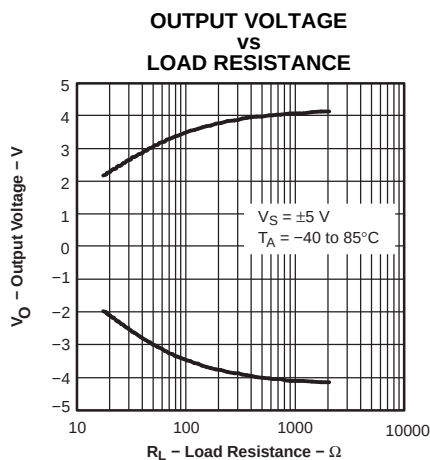
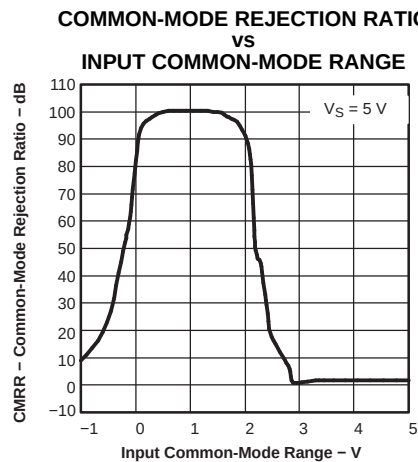
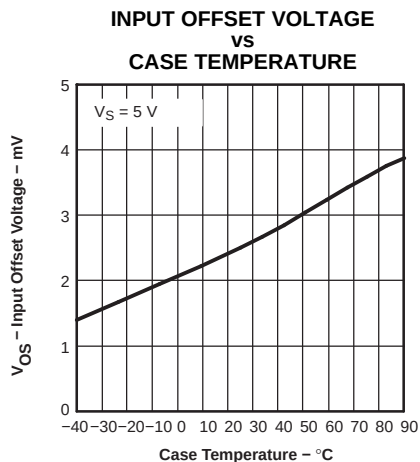
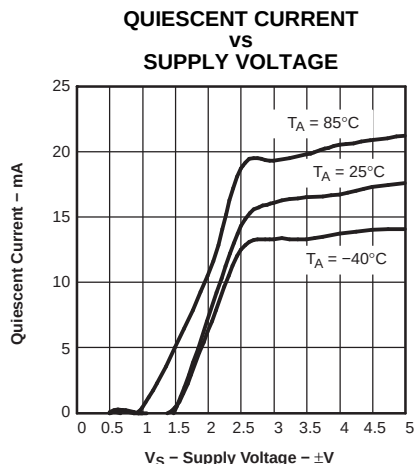


Figure 61.

TYPICAL CHARACTERISTICS: 5 V (continued)



TYPICAL CHARACTERISTICS: 5 V (continued)

TURN-ON AND TURN-OFF
DELAY TIME

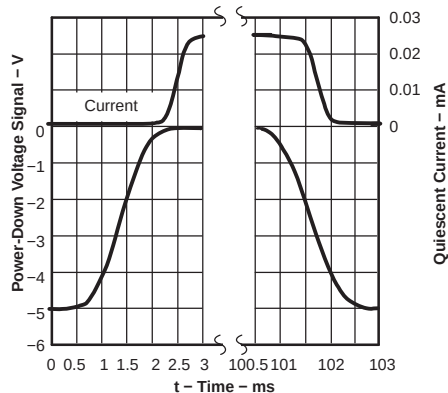


Figure 71.

SINGLE-ENDED OUTPUT
IMPEDANCE
IN POWER-DOWN
VS
FREQUENCY

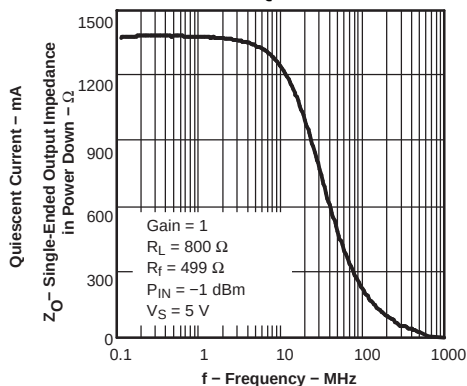


Figure 72.

POWER-DOWN QUIESCENT
CURRENT
VS
CASE TEMPERATURE

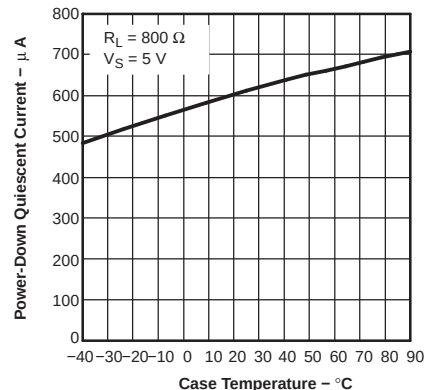


Figure 73.

POWER-DOWN QUIESCENT
CURRENT
VS
SUPPLY VOLTAGE

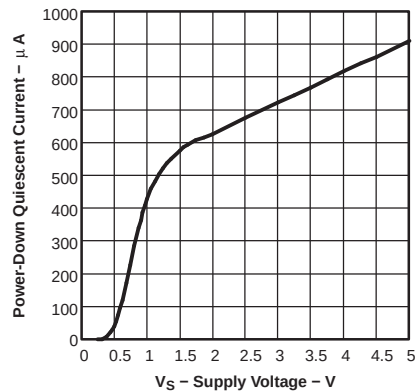


Figure 74.

APPLICATION INFORMATION

FULLY DIFFERENTIAL AMPLIFIERS

Differential signaling offers a number of performance advantages in high-speed analog signal processing systems, including immunity to external common-mode noise, suppression of even-order nonlinearities, and increased dynamic range. Fully differential amplifiers not only serve as the primary means of providing gain to a differential signal chain, but also provide a monolithic solution for converting single-ended signals into differential signals for easier, higher performance processing. The THS4500 family of amplifiers contains the flagship products in Texas Instruments' expanding line of high-performance fully differential amplifiers. Information on fully differential amplifier fundamentals, as well as implementation-specific information, is presented in the applications section of this data sheet to provide a better understanding of the operation of the THS4500 family of devices, and to simplify the design process for designs using these amplifiers.

The THS4504 and THS4505 are intended to be low-cost alternatives to the THS4500/1/2/3 devices. From a topology standpoint, the THS4504/5 have the same architecture as the THS4500/1. Specifically, the input common-mode range is designed to include the negative power supply rail.

Applications Section

- Fully Differential Amplifier Terminal Functions
- Input Common-Mode Voltage Range and the THS4500 Family
- Choosing the Proper Value for the Feedback and Gain Resistors
- Application Circuits Using Fully Differential Amplifiers
- Key Design Considerations for Interfacing to an Analog-to-Digital Converter
- Setting the Output Common-Mode Voltage With the V_{OCM} Input
- Saving Power with Power-Down Functionality
- Linearity: Definitions, Terminology, Circuit Techniques, and Design Tradeoffs
- An Abbreviated Analysis of Noise in Fully Differential Amplifiers
- Printed-Circuit Board Layout Techniques for Optimal Performance
- Power Dissipation and Thermal Considerations
- Power-Supply Decoupling Techniques and Recommendations
- Evaluation Fixtures, Spice Models, and Applications Support

- Additional Reference Material

FULLY DIFFERENTIAL AMPLIFIER TERMINAL FUNCTIONS

Fully differential amplifiers are typically packaged in eight-pin packages as shown in the diagram. The device pins include two inputs (V_{IN+} , V_{IN-}), two outputs (V_{OUT-} , V_{OUT+}), two power supplies (V_{S+} , V_{S-}), an output common-mode control pin (V_{OCM}), and an optional power-down pin ($\overline{PD}$).

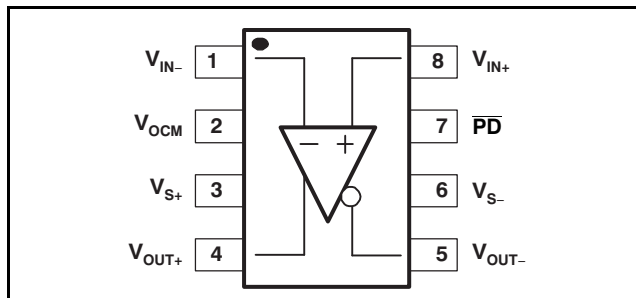


Figure 75. Fully Differential Amplifier Pin Diagram

A standard configuration for the device is shown in the figure. The functionality of a fully differential amplifier can be imagined as two inverting amplifiers that share a common noninverting terminal (though the voltage is not necessarily fixed). For more information on the basic theory of operation for fully differential amplifiers, refer to the Texas Instruments application note titled *Fully Differential Amplifiers* (SLOA054).

INPUT COMMON-MODE VOLTAGE RANGE AND THE THS4500 FAMILY

The key difference between the THS4500/1 and the THS4502/3 is the input common-mode range for the four devices. The input common-mode range of the THS4504/5 is the same as the THS4500/1. The THS4502 and THS4503 have an input common-mode range that is centered around midrail, and the THS4500 and THS4501 have an input common-mode range that is shifted to include the negative power supply rail. Selection of one or the other is determined by the nature of the application. Specifically, the THS4500 and THS4501 are designed for use in single-supply applications where the input signal is ground-referenced, as depicted in [Figure 76](#). The THS4502 and THS4503 are designed for use in single-supply or split-supply applications where the input signal is centered between the power-supply voltages, as depicted in [Figure 77](#).

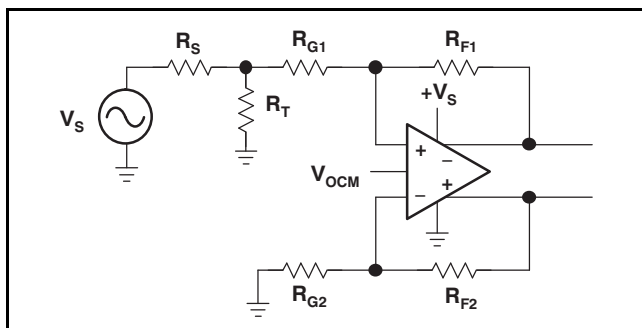


Figure 76. Application Circuit for the THS4500 and THS4501, Featuring Single-Supply Operation with a Ground-Referenced Input Signal

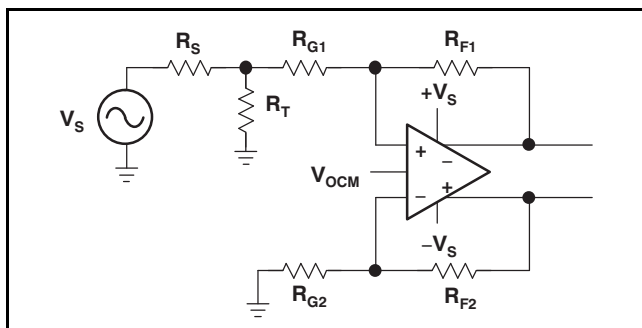


Figure 77. Application Circuit for the THS4500 and THS4501, Featuring Split-Supply Operation with an Input Signal Referenced at the Midrail

Equation 1 to Equation 5 allow calculation of the required input common-mode range for a given set of input conditions.

The equations allow calculation of the input common-mode range requirements given information about the input signal, the output voltage swing, the gain, and the output common-mode voltage. Calculating the maximum and minimum voltage required for V_N and V_P (the amplifier input nodes) determines whether or not the input common-mode range is violated or not. Four equations are required. Two calculate the output voltages and two calculate the node voltages at V_N and V_P (note that only one of these needs calculation, as the amplifier forces a virtual short between the two nodes).

$$V_{OUT+} = \frac{V_{IN+}(1 - \beta) - V_{IN-}(1 - \beta) + 2V_{OCM}\beta}{2\beta} \quad (1)$$

$$V_{OUT-} = \frac{-V_{IN+}(1 - \beta) + V_{IN-}(1 - \beta) + 2V_{OCM}\beta}{2\beta} \quad (2)$$

$$V_N = V_{IN-}(1 - \beta) + V_{OUT+}\beta \quad (3)$$

Where:

$$\beta = \frac{R_G}{R_F + R_G} \quad (4)$$

$$V_P = V_{IN+}(1 - \beta) + V_{OUT-}\beta \quad (5)$$

NOTE:

The equations denote the device inputs as V_N and V_P , and the circuit inputs as V_{IN+} and V_{IN-} .

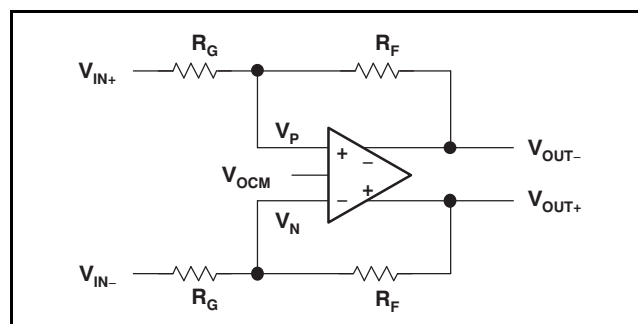


Figure 78. Diagram for Input Common-Mode Range Equations

Table 1 and Table 2 show the input common-mode range requirements for two different input scenarios, an input referenced around the negative rail and an input referenced around midrail. The tables highlight the differing requirements on input common-mode range, and illustrate reasoning for choosing either the THS4500/1 or the THS4502/3. For signals referenced around the negative power supply, the THS4500/1 should be chosen since its input common-mode range includes the negative supply rail. For all other situations, the THS4502/3 offers slightly improved distortion and noise performance for applications with input signals centered between the power-supply rails.

Table 1. Negative-Rail Referenced

Gain (V/V)	V_{IN+} (V)	V_{IN-} (V)	V_{IN} (V _{PP})	V_{OCM} (V)	V_{OD} (V _{PP})	V_{NMIN} (V)	V_{NMAX} (V)
1	–2.0 to 2.0	0	4	2.5	4	0.75	1.75
2	–1.0 to 1.0	0	2	2.5	4	0.5	1.167
4	–0.5 to 0.5	0	1	2.5	4	0.3	0.7
8	–0.25 to 0.25	0	0.5	2.5	4	0.167	0.389

CHOOSING THE PROPER VALUE FOR THE FEEDBACK AND GAIN RESISTORS

The selection of feedback and gain resistors impacts circuit performance in a number of ways. The values in this section provide the optimum high-frequency performance (lowest distortion, flat frequency response). Since the THS4500 family of amplifiers is developed with a voltage-feedback architecture, the choice of resistor values does not have a dominant effect on bandwidth, unlike a current-feedback amplifier. However, resistor choices do have second-order effects. For optimal performance, the following feedback resistor values are recommended. In higher gain configurations (gain greater than two), the feedback resistor values have much less effect on the high-frequency performance. Example feedback and gain resistor values are given in the section on basic design considerations (Table 3).

Amplifier loading, noise, and the flatness of the frequency response are three design parameters that should be considered when selecting feedback resistors. Larger resistor values contribute more noise and can induce peaking in the ac response in low gain configurations, and smaller resistor values can load the amplifier more heavily, resulting in a reduction in distortion performance. In addition, feedback resistor values, coupled with gain

requirements, determine the value of the gain resistors, directly impacting the input impedance of the entire circuit. While there are no strict rules about resistor selection, these trends can provide qualitative design guidance.

APPLICATION CIRCUITS USING FULLY DIFFERENTIAL AMPLIFIERS

Fully differential amplifiers provide designers with a great deal of flexibility in a wide variety of applications. This section provides an overview of some common circuit configurations and gives some design guidelines. Designing the interface to an ADC, driving lines differentially, and filtering with fully differential amplifiers are a few of the circuits that are covered.

Table 2. Midrail Referenced

Gain (V/V)	V _{IN+} (V)	V _{IN-} (V)	V _{IN} (V _{PP})	V _{OCM} (V)	V _{OD} (V _{PP})	V _{NMIN} (V)	V _{NMAX} (V)
1	0.5 to 4.5	2.5	4	2.5	4	2	3
2	1.5 to 3.5	2.5	2	2.5	4	2.16	2.83
4	2.0 to 3.0	2.5	1	2.5	4	2.3	2.7
8	2.25 to 2.75	2.5	0.5	2.5	4	2.389	2.61

Table 3. Resistor Values for Balanced Operation in Various Gain Configurations

Gain $\left(\frac{V_{OD}}{V_{IN}} \right)$	R2 & R4 (Ω)	R1 (Ω)	R3 (Ω)	R _T (Ω)
1	392	412	383	54.9
1	499	523	487	53.6
2	392	215	187	60.4
2	1.3 k	665	634	52.3
5	1.3 k	274	249	56.2
5	3.32 k	681	649	52.3
10	1.3 k	147	118	64.9
10	6.81 k	698	681	52.3

BASIC DESIGN CONSIDERATIONS

The circuits in [Figure 76](#) through [Figure 78](#) are used to highlight basic design considerations for fully differential amplifier circuit designs.

Equations for calculating fully differential amplifier resistor values in order to obtain balanced operation in the presence of a 50-Ω source impedance are given in [Equation 6](#) through [Equation 9](#).

$$R_T = \frac{1}{\frac{1}{R_S} - \frac{1 - \frac{K}{2(1+K)}}{R_3}} \quad K = \frac{R_2}{R_1} \quad R_2 = R_4$$

$$R_3 = R_1 - (R_S \parallel R_T) \quad (6)$$

$$\beta_1 = \frac{R_1}{R_1 + R_2} \quad \beta_2 = \frac{R_3 + R_T \parallel R_S}{R_3 + R_T \parallel R_S + R_4} \quad (7)$$

$$\frac{V_{OD}}{V_S} = 2 \left[\frac{1 - \beta_2}{\beta_1 + \beta_2} \right] \left[\frac{R_T}{R_T + R_S} \right] \quad (8)$$

$$\frac{V_{OD}}{V_{IN}} = 2 \left[\frac{1 - \beta_2}{\beta_1 + \beta_2} \right] \quad (9)$$

For more detailed information about balance in fully differential amplifiers, see the *Fully Differential Amplifiers*, referenced at the end of this data sheet.

INTERFACING TO AN ANALOG-TO-DIGITAL CONVERTER

The THS4500 family of amplifiers are designed specifically to interface to today's highest-performance analog-to-digital converters. This section highlights the key concerns when interfacing to an ADC and provides example ADC/fully differential amplifier interface circuits.

Key design concerns when interfacing to an analog-to-digital converter:

- Terminate the input source properly. In high-frequency receiver chains, the source feeding the fully differential amplifier requires a specific load impedance (for example, 50 Ω).
- Design a symmetric printed-circuit board (PCB) layout. Even-order distortion products are heavily influenced by layout, and careful attention to a symmetric layout will minimize these distortion products.
- Minimize inductance in power-supply decoupling traces and components. Poor power-supply decoupling can have a dramatic effect on circuit performance. Since the outputs are differential, differential currents exist in the power-supply pins. Thus, decoupling capacitors should be placed in a manner that minimizes the impedance of the current loop.

- Use separate analog and digital power supplies and grounds. Noise (bounce) in the power supplies (created by digital switching currents) can couple directly into the signal path, and power-supply noise can create higher distortion products as well.
- Use care when filtering. While an RC low-pass filter may be desirable on the output of the amplifier to filter broadband noise, the excess loading can negatively impact the amplifier linearity. Filtering in the feedback path does not have this effect.
- AC-coupling allows easier circuit design. If dc-coupling is required, be aware of the excess power dissipation that can occur due to level-shifting the output through the output common-mode voltage control.
- Do not terminate the output unless required. Many open-loop, class-A amplifiers require 50-Ω termination for proper operation, but closed-loop fully differential amplifiers drive a specific output voltage regardless of the load impedance present. Terminating the output of a fully differential amplifier with a heavy load adversely effects the amplifier's linearity.
- Comprehend the V_{OCM} input drive requirements. Determine if the ADC voltage reference can provide the required amount of current to move V_{OCM} to the desired value. A buffer may be needed.
- Decouple the V_{OCM} pin to eliminate the antenna effect. V_{OCM} is a high-impedance node that can act as an antenna. A large decoupling capacitor on this node eliminates this problem.
- Be cognizant of the input common-mode range. If the input signal is referenced around the negative power supply rail (e.g., around ground on a single 5 V supply), then the THS4500/1 accommodates the input signal. If the input signal is referenced around midrail, choose the THS4502/3 for the best operation.
- Packaging makes a difference at higher frequencies. If possible, choose the smaller, thermally-enhanced MSOP package for the best performance. As a rule, lower junction temperatures provide better performance. If possible, use a thermally-enhanced package, even if the power dissipation is relatively small compared to the maximum power dissipation rating to achieve the best results.
- Comprehend the effect of the load impedance seen by the fully differential amplifier when performing system-level intercept point calculations. Lighter loads (such as those presented by an ADC) allow smaller intercept points to support the same level of intermodulation distortion performance.

EXAMPLE ANALOG-TO-DIGITAL CONVERTER DRIVER CIRCUITS

The THS4500 family of devices is designed to drive high-performance ADCs with extremely high linearity, allowing for the maximum effective number of bits at the output of the data converter. Two representative circuits shown below highlight single-supply operation and split supply operation. Specific feedback resistor, gain resistor, and feedback capacitor values are not specified, as their values depend on the frequency of interest. Information on calculating these values can be found in the applications material above.

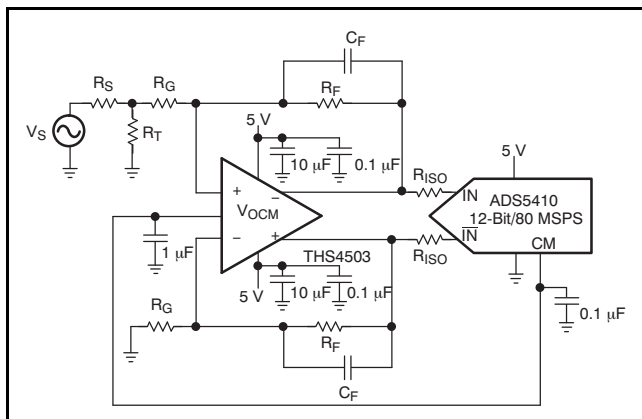


Figure 79. Using the THS4503 with the ADS5410

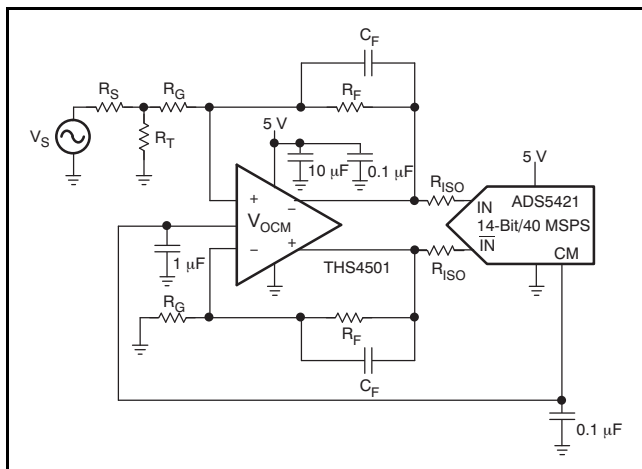


Figure 80. Using the THS4501 with the ADS5421

FULLY DIFFERENTIAL LINE DRIVERS

The THS4500 family of amplifiers can be used as high-frequency, high-swing differential line drivers. Their high power supply voltage rating (16.5 V absolute maximum) allows operation on a single 12-V or a single 15-V supply. The high supply voltage, coupled with the ability to provide differential outputs enables the ability to drive 26 V_{PP} into reasonably heavy loads (250 Ω or greater). The circuit in

Figure 81 illustrates the THS4500 family of devices used as high speed line drivers. For line driver applications, close attention must be paid to thermal design constraints due to the typically high level of power dissipation.

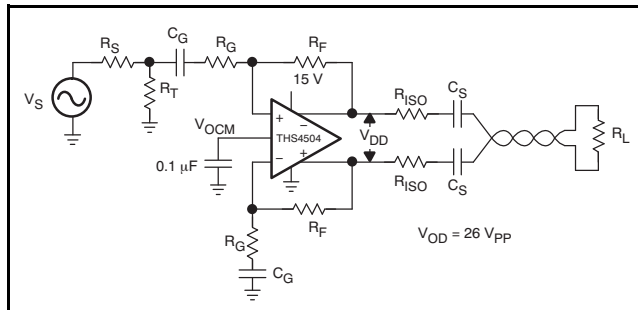


Figure 81. Fully Differential Line Driver with High Output Swing

FILTERING WITH FULLY DIFFERENTIAL AMPLIFIERS

Similar to their single-ended counterparts, fully differential amplifiers have the ability to couple filtering functionality with voltage gain. Numerous filter topologies can be based on fully differential amplifiers. Several of these are outlined in *A Differential Circuit Collection (SLOA064)*, referenced at the end of this data sheet. The circuit in Figure 82 depicts a simple two-pole low-pass filter applicable to many different types of systems. The first pole is set by the resistors and capacitors in the feedback paths, and the second pole is set by the isolation resistors and the capacitor across the outputs of the isolation resistors.

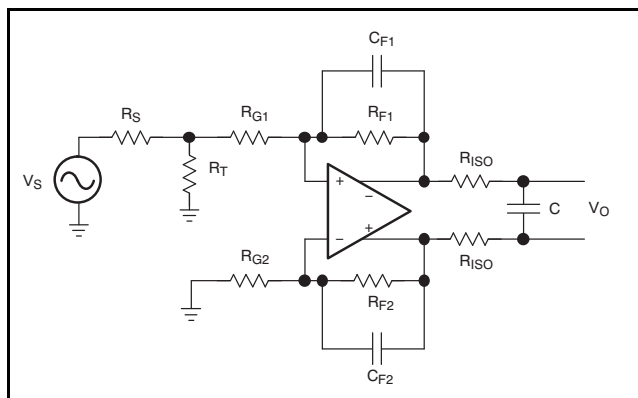


Figure 82. A Two-Pole, Low-Pass Filter Design Using a Fully Differential Amplifier with Poles Located at $P1 = (2 \times R_F C_F)^{-1}$ in Hz and $P2 = (4 \times R_{ISO} C)^{-1}$ in Hz

Often times, filters like these are used to eliminate broadband noise and out-of-band distortion products in signal acquisition systems. It should be noted that the increased load placed on the output of the amplifier by the second low-pass filter has a detrimental effect on the distortion performance. The preferred method of filtering is using the feedback network, as the typically smaller capacitances required at these points in the circuit do not load the amplifier nearly as heavily in the pass-band.

SETTING THE OUTPUT COMMON-MODE VOLTAGE WITH THE V_{OCM} INPUT

The output common-mode voltage pin provides a critical function to the fully differential amplifier; it accepts an input voltage and reproduces that input voltage as the output common-mode voltage. In other words, the V_{OCM} input provides the ability to level-shift the outputs to any voltage inside the output voltage swing of the amplifier.

A description of the input circuitry of the V_{OCM} pin is shown below to facilitate an easier understanding of the V_{OCM} interface requirements. The V_{OCM} pin has two 50-k Ω resistors between the power supply rails to set the default output common-mode voltage to midrail. A voltage applied to the V_{OCM} pin alters the output common-mode voltage as long as the source has the ability to provide enough current to overdrive the two 50-k Ω resistors. This phenomenon is depicted in the V_{OCM} equivalent circuit diagram. Current drive is especially important when using the reference voltage of an analog-to-digital converter to drive V_{OCM} . Output current drive capabilities differ from part to part, so a voltage buffer may be necessary in some applications.

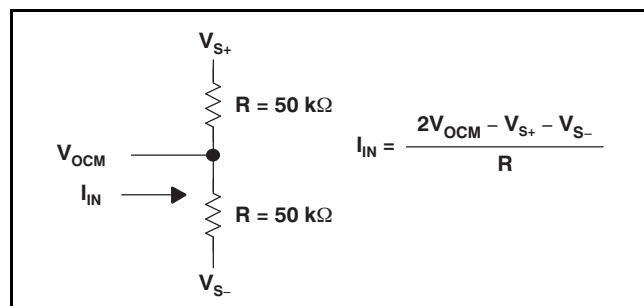


Figure 83. Equivalent Input Circuit for V_{OCM}

By design, the input signal applied to the V_{OCM} pin propagates to the outputs as a common-mode signal. As shown in the equivalent circuit diagram, the V_{OCM} input has a high impedance associated with it, dictated by the two 50-k Ω resistors. While the high impedance allows for relaxed drive requirements, it also allows the pin and any associated printed-circuit board traces to act as an antenna. For this reason, a decoupling capacitor is recommended on this node

for the sole purpose of filtering any high frequency noise that could couple into the signal path through the V_{OCM} circuitry. A 0.1- μ F or 1- μ F capacitance is a reasonable value for eliminating a great deal of broadband interference, but additional, tuned decoupling capacitors should be considered if a specific source of electromagnetic or radio frequency interference is present elsewhere in the system. Information on the ac performance (bandwidth, slew rate) of the V_{OCM} circuitry is included in the specification table and graph section.

Since the V_{OCM} pin provides the ability to set an output common-mode voltage, the ability for increased power dissipation exists. While this does not pose a performance problem for the amplifier, it can cause additional power dissipation of which the system designer should be aware. The circuit shown in Figure 84 demonstrates an example of this phenomenon. For a device operating on a single 5-V supply with an input signal referenced around ground and an output common-mode voltage of 2.5 V, a dc potential exists between the outputs and the inputs of the device. The amplifier sources current into the feedback network in order to provide the circuit with the proper operating point. While there are no serious effects on the circuit performance, the extra power dissipation may need to be included in the system power budget.

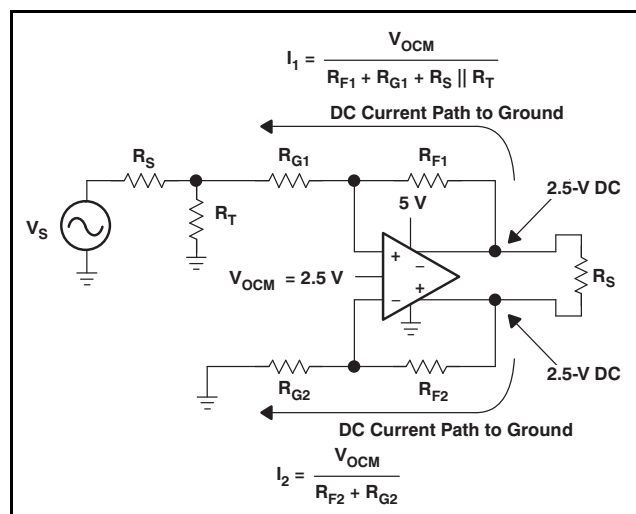


Figure 84. Depiction of DC Power Dissipation Caused by Output Level-Shifting in a DC-Coupled Circuit

SAVING POWER WITH POWER-DOWN FUNCTIONALITY

The THS4500 family of fully differential amplifiers contains devices that come with and without the power-down option. Even-numbered devices have power-down capability, which is described in detail here.

The power-down pin of the amplifiers defaults to the positive supply voltage in the absence of an applied voltage (i.e. an internal pullup resistor is present), putting the amplifier in the *power-on* mode of operation. To turn off the amplifier in an effort to conserve power, the power-down pin can be driven towards the negative rail. The threshold voltages for power-on and power-down are relative to the supply rails and given in the specification tables. Above the *enable threshold voltage*, the device is on. Below the *disable threshold voltage*, the device is off. Behavior in between these threshold voltages is not specified.

Note that this power-down functionality is just that; the amplifier consumes less power in power-down mode. The power-down mode is not intended to provide a high-impedance output. In other words, the power-down functionality is not intended to allow use as a 3-state bus driver. When in power-down mode, the impedance looking back into the output of the amplifier is dominated by the feedback and gain setting resistors.

The time delays associated with turning the device on and off are specified as the time it takes for the amplifier to reach 50% of the nominal quiescent current. The time delays are on the order of microseconds because the amplifier moves in and out of the linear mode of operation in these transitions.

LINEARITY: DEFINITIONS, TERMINOLOGY, CIRCUIT TECHNIQUES, AND DESIGN TRADEOFFS

The THS4500 family of devices features unprecedented distortion performance for monolithic fully differential amplifiers. This section focuses on the fundamentals of distortion, circuit techniques for reducing nonlinearity, and methods for equating distortion of fully differential amplifiers to desired linearity specifications in RF receiver chains.

Amplifiers are generally thought of as *linear* devices. In other words, the output of an amplifier is a linearly scaled version of the input signal applied to it. In reality, however, amplifier transfer functions are nonlinear. Minimizing amplifier nonlinearity is a primary design goal in many applications.

Intercept points are specifications that have long been used as key design criteria in the RF communications world as a metric for the intermodulation distortion performance of a device in the signal chain (for example, amplifiers, mixers, etc.). Use of the intercept point, rather than strictly the intermodulation distortion, allows for simpler system-level calculations. Intercept points, like noise figures, can be easily cascaded back and forth through a signal chain to determine the overall receiver chain intermodulation distortion performance. The relationship between intermodulation distortion and intercept point is depicted in [Figure 85](#) and [Figure 86](#).

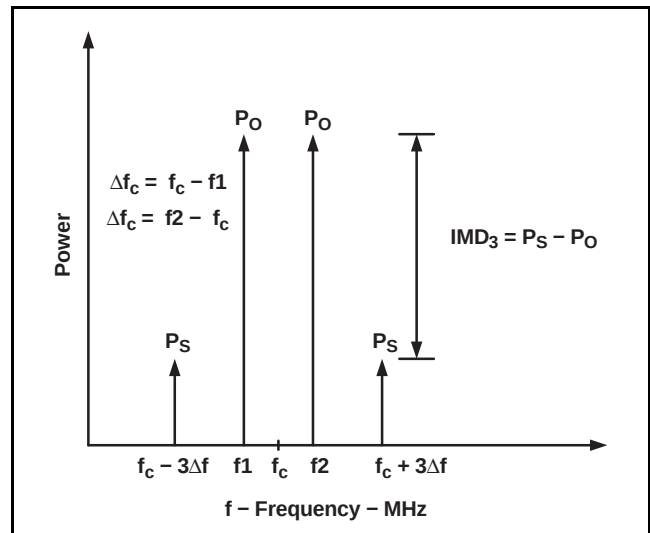


Figure 85. 2-Tone and 3rd-Order Intermodulation Products

Due to the intercept point's ease of use in system level calculations for receiver chains, it has become the specification of choice for guiding distortion-related design decisions. Traditionally, these systems use primarily class-A, single-ended RF amplifiers as gain blocks. These RF amplifiers are typically designed to operate in a 50-Ω environment, just like the rest of the receiver chain. Since intercept points are given in dBm, this implies an associated impedance (50 Ω).

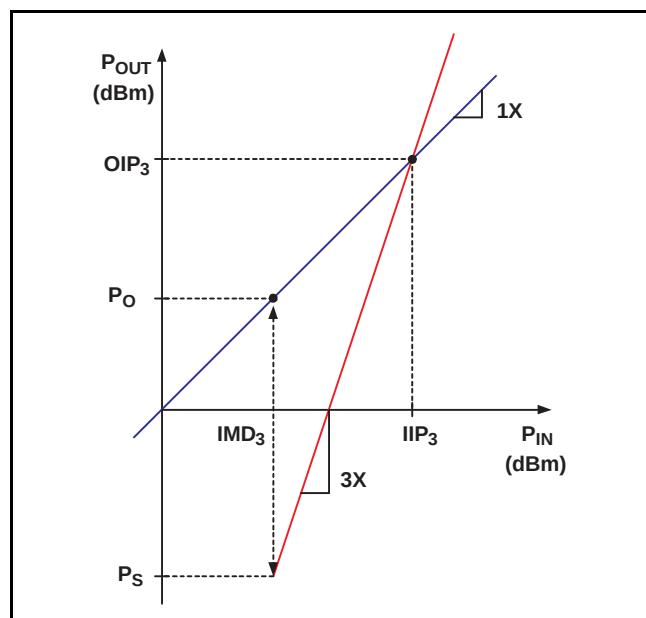


Figure 86. Graphical Representation of 2-Tone and 3rd-Order Intercept Point

However, with a fully differential amplifier, the output does not require termination as an RF amplifier would. Because closed-loop amplifiers deliver signals to their outputs regardless of the impedance present, it is important to comprehend this when evaluating the intercept point of a fully differential amplifier. The THS4500 series of devices yields optimum distortion performance when loaded with 200 Ω to 1 k Ω , very similar to the input impedance of an analog-to-digital converter over its input frequency band. As a result, terminating the input of the ADC to 50 Ω can actually be detrimental to system performance.

This discontinuity between open-loop, class-A amplifiers and closed-loop, class-AB amplifiers becomes apparent when comparing the intercept points of the two types of devices. Equation 10 gives the definition of an intercept point, relative to the intermodulation distortion.

$$OIP_3 = P_O + \left[\frac{|IMD_3|}{2} \right] \quad (10)$$

$$P_O = 10 \log \left[\frac{V_{P_{diff}}^2}{2R_L \times 0.001} \right] \quad (11)$$

NOTE: P_O is the output power of a single tone, R_L is the differential load resistance, and $V_{P_{diff}}$ is the differential peak voltage for a single tone.

As can be seen in the equation, when a higher impedance is used, the same level of intermodulation distortion performance results in a lower intercept point. Therefore, it is important to comprehend the impedance seen by the output of the fully differential amplifier when selecting a minimum intercept point. The graphic below shows the relationship between the strict definition of an intercept point with a normalized, or equivalent, intercept point for the THS4504.

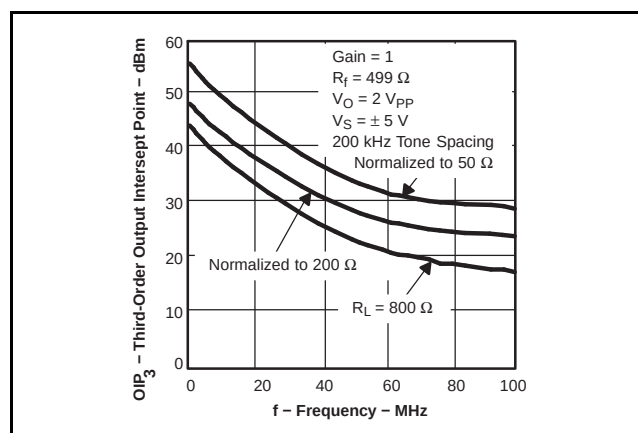


Figure 87. Equivalent 3rd-Order Intercept Point for the THS4504

Comparing specifications between different device types becomes easier when a common impedance level is assumed. For this reason, the intercept points on the THS4500 family of devices are reported normalized to a 50- Ω load impedance.

AN ANALYSIS OF NOISE IN FULLY DIFFERENTIAL AMPLIFIERS

Noise analysis in fully differential amplifiers is analogous to noise analysis in single-ended amplifiers. The same concepts apply. Below, a generic circuit diagram consisting of a voltage source, a termination resistor, two gain setting resistors, two feedback resistors, and a fully differential amplifier is shown, including all the relevant noise sources. From this circuit, the noise factor (F) and noise figure (NF) are calculated. The figures indicate the appropriate scaling factor for each of the noise sources in two different cases. The first case includes the termination resistor, and the second, simplified case assumes that the voltage source is properly terminated by the gain-setting resistors. With these scaling factors, the amplifier's input noise power (N_A) can be calculated by summing each individual noise source with its scaling factor. The noise delivered to the amplifier by the source (N_i) and input noise power are used to calculate the noise factor and noise figure as shown in Equation 23 through Equation 27.

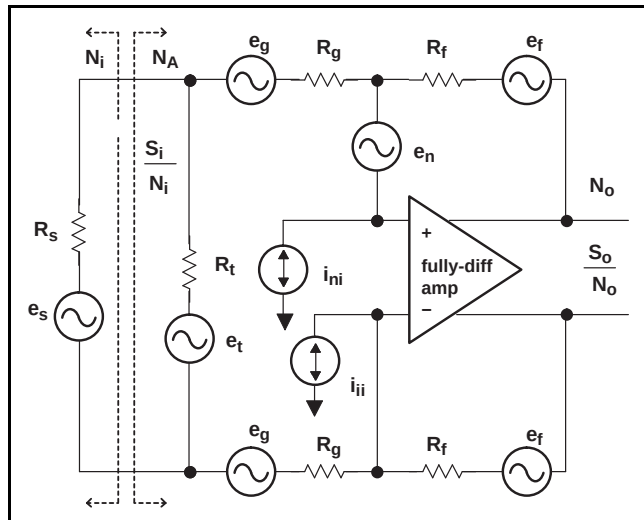


Figure 88. Noise Sources in a Fully Differential Amplifier Circuit

Scaling Factors for Individual Noise Sources Assuming a Finite Value Termination Resistor

$$(e_{ni})^2 = \left(\frac{R_G}{R_F} + \frac{R_G}{R_G + \frac{R_S R_T}{2(R_S + R_T)}} \right)^2 \quad (12)$$

$$(i_{ni})^2 = R_G^2 \quad (13)$$

$$(i_{ij})^2 = R_G^2 \quad (14)$$

$$4kTR_F = \left(\frac{\frac{2R_S R_G}{R_S + 2R_G}}{R_T + \frac{2R_S R_G}{R_S + 2R_G}} \right)^2 \quad (15)$$

$$4kTR_F = 2 \times \left(\frac{R_G}{R_F} \right)^2 \quad (16)$$

$$4kTR_G = 2 \times \left(\frac{R_G}{R_G + \frac{R_S R_T}{2(R_S + R_T)}} \right)^2 \quad (17)$$

Scaling Factors for Individual Noise Sources Assuming No Termination Resistance is Used (for example, R_T is open)

$$(e_{ni})^2 = \left(\frac{R_G}{R_F} + \frac{R_G}{R_G + \frac{R_S}{2}} \right)^2 \quad (18)$$

$$(i_{ni})^2 = R_G^2 \quad (19)$$

$$(i_{ij})^2 = R_G^2 \quad (20)$$

$$4kTR_F = 2 \times \left(\frac{R_G}{R_F} \right)^2 \quad (21)$$

$$4kTR_G = 2 \times \left(\frac{R_G}{R_G + \frac{R_S}{2}} \right)^2 \quad (22)$$

Input Noise With a Termination Resistor:

$$N_i = 4kTR_S \left(\frac{\frac{2R_T R_G}{R_T + 2R_G}}{R_S + \frac{2R_T R_G}{R_T + 2R_G}} \right)^2 \quad (23)$$

Input Noise Assuming No Termination Resistor:

$$N_i = 4kTR_S \left(\frac{2R_G}{R_S + 2R_G} \right)^2 \quad (24)$$

Noise Factor and Noise Figure Calculations

$$N_A = \Sigma (\text{Noise Source} \times \text{Scale Factor}) \quad (25)$$

$$F = 1 + \frac{N_A}{N_i} \quad (26)$$

$$NF = 10 \log (F) \quad (27)$$

PC BOARD LAYOUT TECHNIQUES FOR OPTIMAL PERFORMANCE

Achieving optimum performance with a high frequency amplifier-like devices in the THS4500 family requires careful attention to board layout parasitic and external component types.

Recommendations that optimize performance include:

- Minimize parasitic capacitance to any ac ground for all of the signal I/O pins. Parasitic capacitance on the output and input pins can cause instability. To reduce unwanted capacitance, a window around the signal I/O pins should be opened in all of the ground and power planes around those pins. Otherwise, ground and power planes should be unbroken elsewhere on the board.
- Minimize the distance ($< 0.25"$) from the power-supply pins to high-frequency $0.1\text{-}\mu\text{F}$ decoupling capacitors. At the device pins, the ground and power-plane layout should not be in close proximity to the signal I/O pins. Avoid narrow power and ground traces to minimize inductance between the pins and the decoupling capacitors. The power-supply connections should always be decoupled with these capacitors. Larger ($6.8\text{ }\mu\text{F}$ or more) tantalum decoupling capacitors, effective at lower frequency, should also be used on the main supply pins. These may be placed somewhat farther from the device and may be shared among several devices in the same area of the PC board. The primary goal is to minimize the impedance seen in the differential-current return paths.
- Careful selection and placement of external components preserve the high frequency performance of the THS4500 family. Resistors should be a very low reactance type. Surface-mount resistors work best and allow a tighter overall layout. Metal-film and carbon composition, axially-leaded resistors can also provide good high frequency performance. Again, keep their leads and PC board trace length as short as possible. Never use wirewound type resistors in a high-frequency application. Since the output pin and inverting input pins are the most sensitive to parasitic capacitance, always position the feedback and series output resistors, if any, as close as possible to the inverting input pins and output pins. Other network components, such as input termination resistors, should be placed close to the gain-setting resistors. Even with a low parasitic capacitance shunting the external resistors, excessively high resistor values can create significant time constants that can degrade performance. Good axial metal-film or surface-mount resistors have approximately 0.2 pF in shunt with the resistor. For resistor values $> 2.0\text{ k}\Omega$, this parasitic capacitance can add a pole and/or a zero below 400 MHz that can effect circuit operation. Keep resistor values as low as possible, consistent with load driving considerations.
- Connections to other wideband devices on the board may be made with short direct traces or through onboard transmission lines. For short connections, consider the trace and the input to the next device as a lumped capacitive load. Relatively wide traces (50 mils to 100 mils) should be used, preferably with ground and power planes opened up around them. Estimate the total capacitive load and determine if isolation resistors on the outputs are necessary. Low parasitic capacitive loads ($< 4\text{ pF}$) may not need an R_S since the THS4500 family is nominally compensated to operate with a 2-pF parasitic load. Higher parasitic capacitive loads without an R_S are allowed as the signal gain increases (increasing the unloaded phase margin). If a long trace is required, and the 6-dB signal loss intrinsic to a doubly-terminated transmission line is acceptable, implement a matched impedance transmission line using microstrip or stripline techniques (consult an ECL design handbook for microstrip and stripline layout techniques).
- A $50\text{-}\Omega$ environment is normally not necessary onboard, and in fact, a higher impedance environment improves distortion as shown in the distortion versus load plots. With a characteristic board trace impedance defined based on board material and trace dimensions, a matching series resistor into the trace from the output of the THS4500 family is used as well as a terminating shunt resistor at the input of the destination device.
- Remember also that the terminating impedance is the parallel combination of the shunt resistor and the input impedance of the destination device: this total effective impedance should be set to match the trace impedance. If the 6-dB attenuation of a doubly terminated transmission line is unacceptable, a long trace can be series-terminated at the source end only. Treat the trace as a capacitive load in this case. This does not preserve signal integrity as well as a doubly-terminated line. If the input impedance of the destination device is low, there is some signal attenuation due to the voltage divider formed by the series output into the terminating impedance.
- Socketing a high speed part like the THS4500 family is not recommended. The additional lead length and pin-to-pin capacitance introduced by the socket can create an extremely troublesome parasitic network which can make it almost impossible to achieve a smooth, stable frequency response. Best results are obtained by soldering the THS4500 family parts directly onto the board.

PowerPAD DESIGN CONSIDERATIONS

The THS4500 family is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 89(a) and Figure 89(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 89(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the, heretofore, awkward mechanical methods of heatsinking.

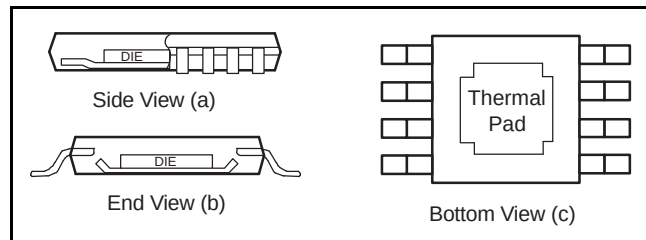


Figure 89. Views of Thermally Enhanced Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

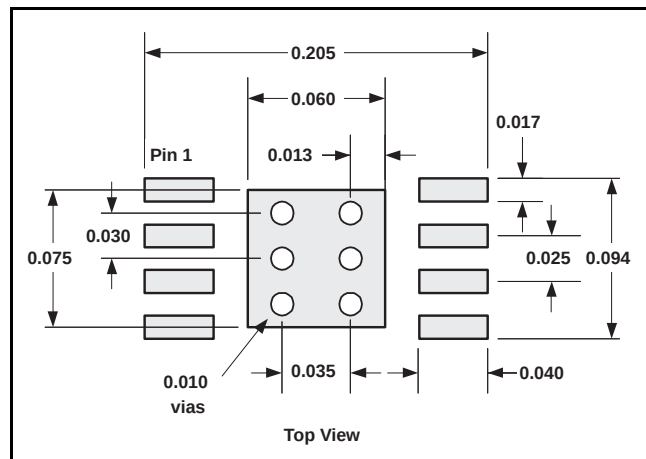


Figure 90. View of Thermally Enhanced Package

PowerPAD PCB LAYOUT CONSIDERATIONS

1. Prepare the PCB with a top side etch pattern as shown in Figure 90. There should be etch for the leads as well as etch for the thermal pad.
2. Place five holes in the area of the thermal pad. These holes should be 13 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.
3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS4500 family IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, **do not** use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS4500 family PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes exposed. The bottom-side solder mask should cover the five holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
8. With these preparatory steps in place, the IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

POWER DISSIPATION AND THERMAL CONSIDERATIONS

The THS4500 family of devices does not incorporate automatic thermal shutoff protection, so the designer must take care to ensure that the design does not violate the absolute maximum junction temperature of the device. Failure may result if the absolute maximum junction temperature of +150°C is exceeded. For best performance, design for a maximum junction temperature of +125°C. Between +125°C and +150°C, damage does not occur, but the performance of the amplifier begins to degrade.

The thermal characteristics of the device are dictated by the package and the PC board. Maximum power dissipation for a given package can be calculated using the following formula.

$$P_{Dmax} = \frac{T_{max} - T_A}{\theta_{JA}} \quad (28)$$

Where:

P_{Dmax} is the maximum power dissipation in the amplifier (W).

T_{MAX} is the absolute maximum junction temperature ($^{\circ}C$).

T_A is the ambient temperature ($^{\circ}\text{C}$).

$$\theta_{1A} = \theta_{1C} + \theta_{CA}$$

θ_{JC} is the thermal coefficient from the silicon junctions to the case ($^{\circ}\text{C}/\text{W}$).

θ_{CA} is the thermal coefficient from the case to ambient air ($^{\circ}\text{C}/\text{w}$).

For systems where heat dissipation is more critical, the THS4500 family of devices is offered in an MSOP-8 with PowerPAD. The thermal coefficient for the MSOP PowerPAD package is substantially improved over the traditional SOIC. Maximum power dissipation levels are depicted in the graph for the two packages. The data for the DGN package assumes a board layout that follows the PowerPAD layout guidelines referenced above and detailed in the PowerPAD application notes in the *Additional Reference Material* section at the end of the data sheet.

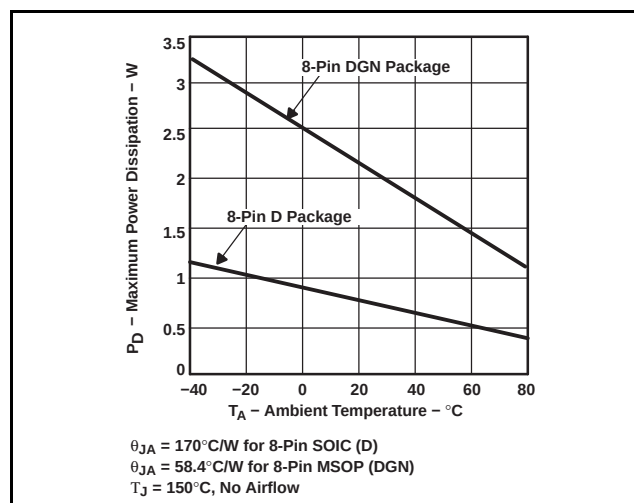


Figure 91. Maximum Power Dissipation vs Ambient Temperature

When determining whether or not the device satisfies the maximum power dissipation requirement, it is important to not only consider quiescent power dissipation, but also dynamic power dissipation. Often times, this is difficult to quantify because the signal pattern is inconsistent, but an estimate of the RMS power dissipation can provide visibility into a possible problem.

DRIVING CAPACITIVE LOADS

High-speed amplifiers are typically not well-suited for driving large capacitive loads. If necessary, however, the load capacitance should be isolated by two isolation resistors in series with the output. The requisite isolation resistor size depends on the value of the capacitance, but 10 Ω to 25 Ω is a good place to begin the optimization process. Larger isolation resistors decrease the amount of peaking in the frequency response induced by the capacitive load, but this comes at the expense of larger voltage drop across the resistors, increasing the output swing requirements of the system.

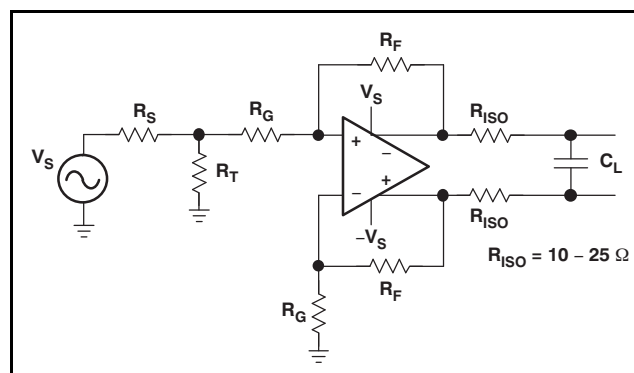


Figure 92. Use of Isolation Resistors with a Capacitive Load

POWER-SUPPLY DECOUPLING TECHNIQUES AND RECOMMENDATIONS

Power-supply decoupling is a critical aspect of any high-performance amplifier design process. Careful decoupling provides higher quality ac performance (most notably improved distortion performance). The following guidelines ensure the highest level of performance.

1. Place decoupling capacitors as close to the power-supply inputs as possible, with the goal of minimizing the inductance of the path from ground to the power supply.
2. Placement priority should be as follows: smaller capacitors should be closer to the device.
3. Use of solid power and ground planes is recommended to reduce the inductance along power-supply return current paths.
4. Recommended values for power supply decoupling include 10- μ F and 0.1- μ F capacitors for each supply. A 1000-pF capacitor can be used across the supplies as well for extremely high-frequency return currents, but often is not required.

EVALUATION FIXTURES, SPICE MODELS, AND APPLICATIONS SUPPORT

Texas Instruments is committed to providing its customers with the highest quality of applications support. To support this goal, an evaluation board has been developed for the THS4500 family of fully differential amplifiers. The evaluation board can be obtained by ordering through the Texas Instruments web site, www.ti.com, or through your local Texas Instruments sales representative. The schematic for the evaluation board is shown in Figure 93 with default component values. Unpopulated footprints are shown to provide insight into design flexibility.

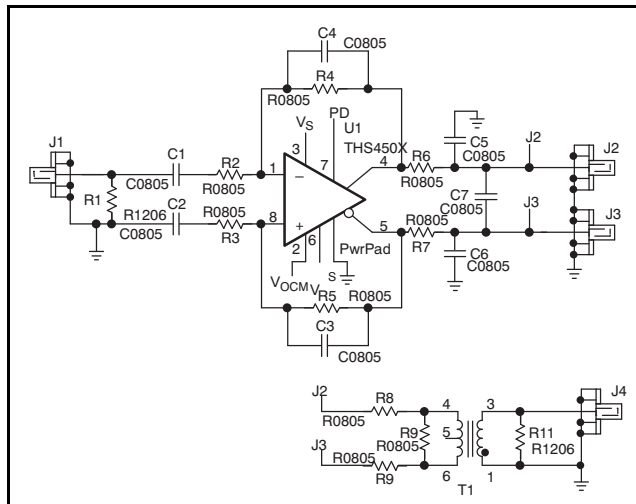


Figure 93. Simplified Schematic of the Evaluation Board. Power-Supply Decoupling, V_{OCM1} , and Power-Down Circuitry not Shown

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. This is particularly true for video and RF amplifier circuits where parasitic capacitance and inductance can have a major effect on circuit performance. A SPICE model for the THS4500 family of devices is available through the Texas Instruments web site (www.ti.com). The Product Information Center (PIC) is available for design assistance and detailed product information. These models do a good job of predicting small-signal ac and transient performance under a wide variety of operating conditions. They are not intended to model the distortion characteristics of the amplifier, nor do they attempt to distinguish between the package types in their small-signal ac performance. Detailed information about what is and is not modeled is contained in the model file itself.

ADDITIONAL REFERENCE MATERIAL

- *PowerPAD Made Easy*, application brief, (SLMA004).
- *PowerPAD Thermally-Enhanced Package*, technical brief, (SLMA002).
- Karki, James. *Fully Differential Amplifiers*. application report, (SLOA054D).
- Karki, James. *Fully Differential Amplifiers Applications: Line Termination, Driving High-Speed ADCs, and Differential Transmission Lines*. Texas Instruments Analog Applications Journal, February 2001.
- Carter, Bruce. *A Differential Op-Amp Circuit Collection*. application report, (SLOA064).
- Carter, Bruce. *Differential Op-Amp Single-Supply Design Technique*, application report, (SLOA072).
- Karki, James. *Designing for Low Distortion with High-Speed Op Amps*. Texas Instruments Analog Applications Journal, July 2001.

Revision History

Changes from Revision C (March 2004) to Revision D	Page
• Updated document format	1
• Added footnote 1 to Ordering Information table	3
• Changed x-axis of Figure 12	11
• Changed x-axis of Figure 49	15
• Changed <i>two</i> to <i>four</i> in first sentence of the Input Common-Mode Voltage Range and the THS4500 Family section	19
• Deleted figure from Basic Design Considerations section.....	22
• Changed cross-references in first sentence of Basic Design Considerations section to Figure 76 through Figure 78	22
• Changed <i>below</i> to <i>in</i> Figure 82 in first paragraph of Filtering with Fully Differential Amplifiers section.....	23
• Removed reference to nonexistent table in second paragraph of Setting the Output Common-Mode Voltage with the V_{OCM} Input section.....	24
• Added titles to Figure 85 , Figure 86 , and Figure 87	25
• Changed <i>THS4502</i> to <i>THS4504</i> in last sentence of eighth paragraph in the Linearity: Definitions, Terminology, Circuit Techniques, and Design Tradeoffs section	25

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
THS4504D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4504
THS4504D.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4504
THS4504DGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ASZ
THS4504DGK.A	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ASZ
THS4504DGN	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	BDB
THS4504DGN.A	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BDB
THS4504DGNR	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	BDB
THS4504DGNR.A	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BDB
THS4504DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4504
THS4504DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4504
THS4505D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4505
THS4505D.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4505
THS4505DGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ATA
THS4505DGK.A	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ATA
THS4505DGKG4	Active	Production	VSSOP (DGK) 8	80 TUBE	-	Call TI	Call TI	-40 to 85	
THS4505DGN	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	BDC
THS4505DGN.A	Active	Production	HVSSOP (DGN) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BDC
THS4505DGNR	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	BDC
THS4505DGNR.A	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BDC
THS4505DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4505
THS4505DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4505

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

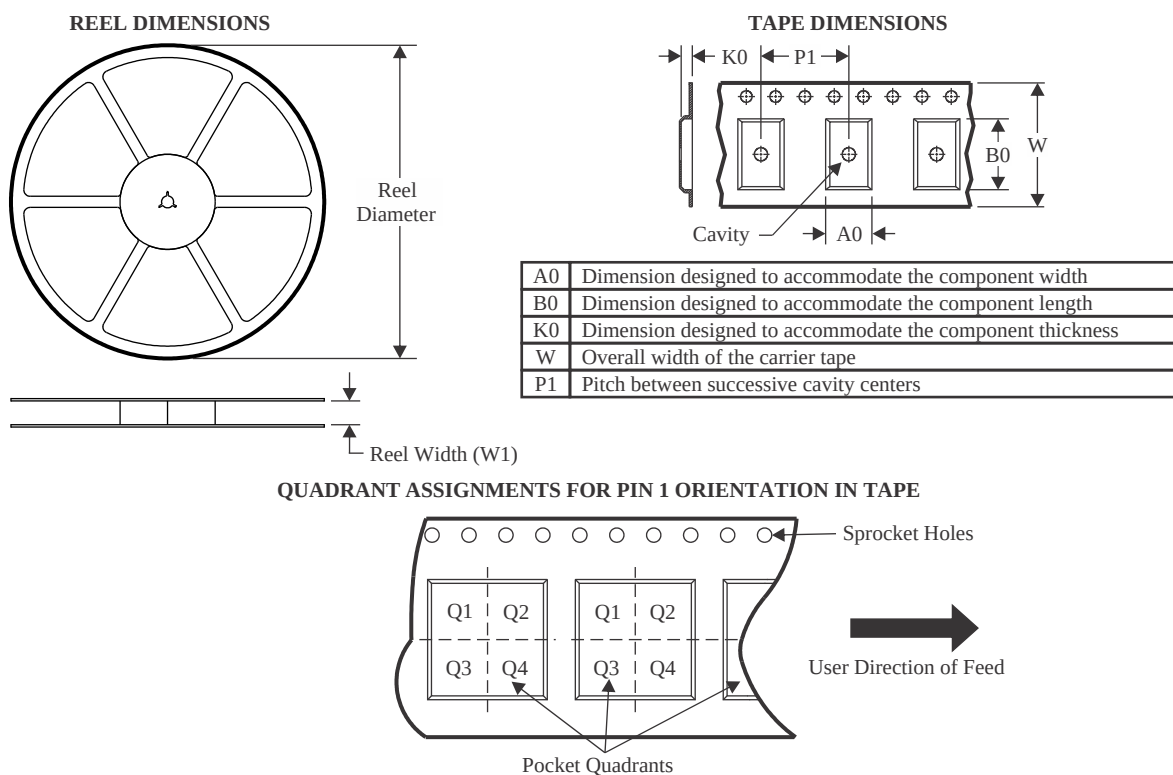
(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

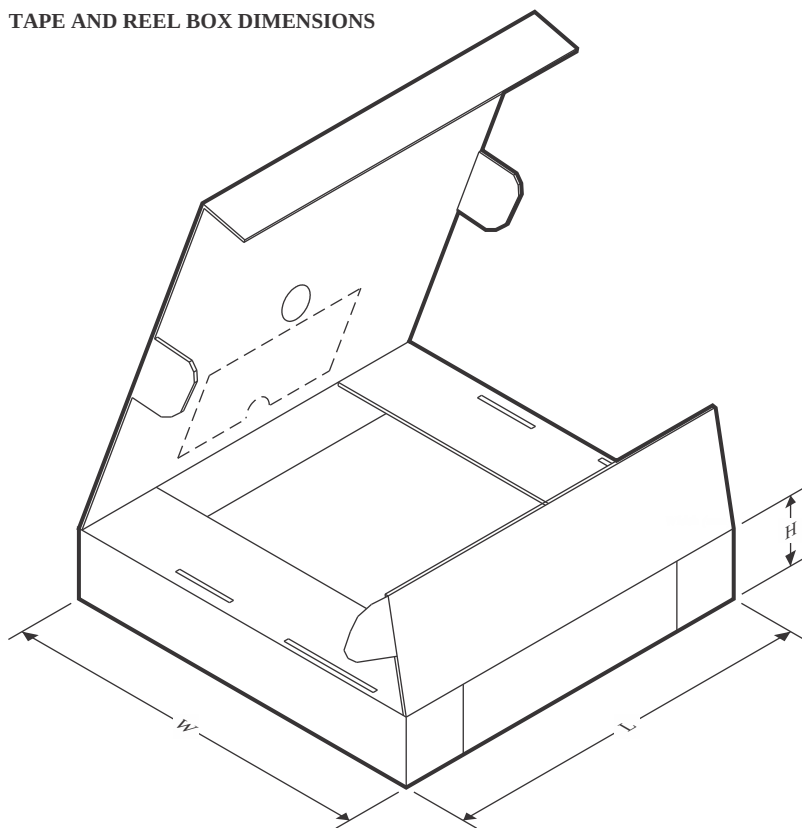
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS4504DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4504DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4504DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4505DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4505DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4505DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

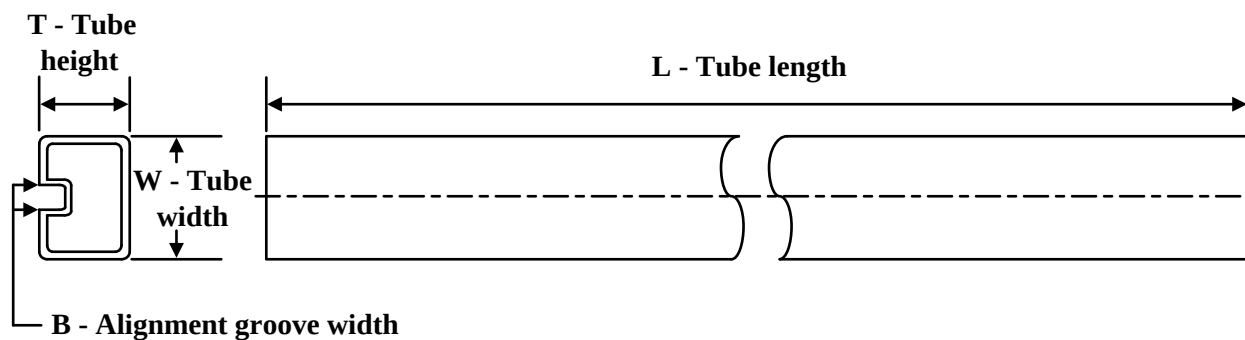
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS4504DGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
THS4504DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
THS4504DR	SOIC	D	8	2500	350.0	350.0	43.0
THS4505DGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
THS4505DGNR	HVSSOP	DGN	8	2500	364.0	364.0	27.0
THS4505DR	SOIC	D	8	2500	350.0	350.0	43.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
THS4504D	D	SOIC	8	75	505.46	6.76	3810	4
THS4504D.A	D	SOIC	8	75	505.46	6.76	3810	4
THS4504DGK	DGK	VSSOP	8	80	274	6.2	2540	2.5
THS4504DGK.A	DGK	VSSOP	8	80	274	6.2	2540	2.5
THS4504DGN	DGN	HVSSOP	8	80	274	6.2	2540	2.5
THS4504DGN	DGN	HVSSOP	8	80	330	6.55	500	2.88
THS4504DGN.A	DGN	HVSSOP	8	80	330	6.55	500	2.88
THS4504DGN.A	DGN	HVSSOP	8	80	274	6.2	2540	2.5
THS4505D	D	SOIC	8	75	505.46	6.76	3810	4
THS4505D.A	D	SOIC	8	75	505.46	6.76	3810	4
THS4505DGK	DGK	VSSOP	8	80	274	6.2	2540	2.5
THS4505DGK.A	DGK	VSSOP	8	80	274	6.2	2540	2.5
THS4505DGN	DGN	HVSSOP	8	80	274	6.2	2540	2.5
THS4505DGN	DGN	HVSSOP	8	80	330	6.55	500	2.88
THS4505DGN.A	DGN	HVSSOP	8	80	274	6.2	2540	2.5
THS4505DGN.A	DGN	HVSSOP	8	80	330	6.55	500	2.88

GENERIC PACKAGE VIEW

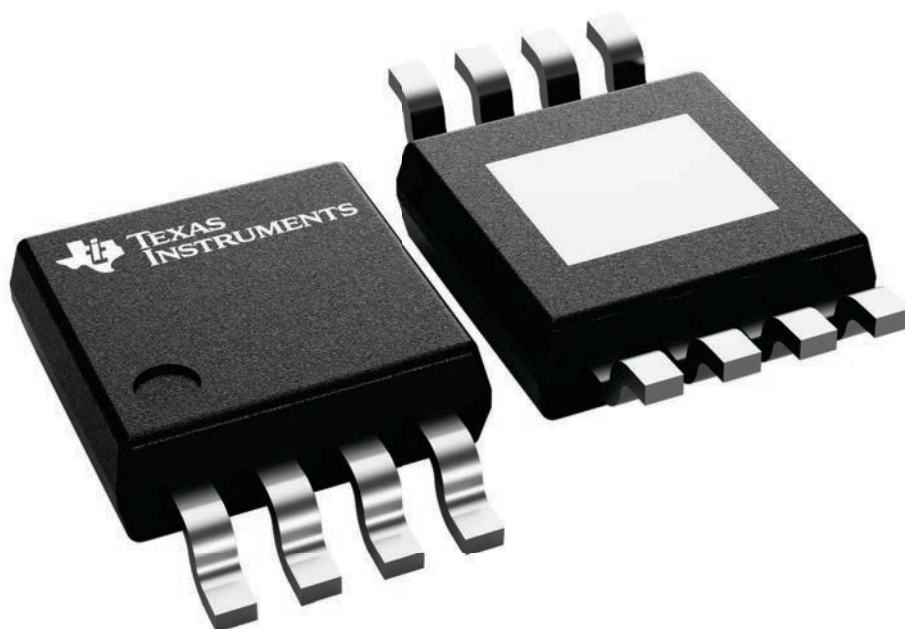
DGN 8

PowerPAD™ HVSSOP - 1.1 mm max height

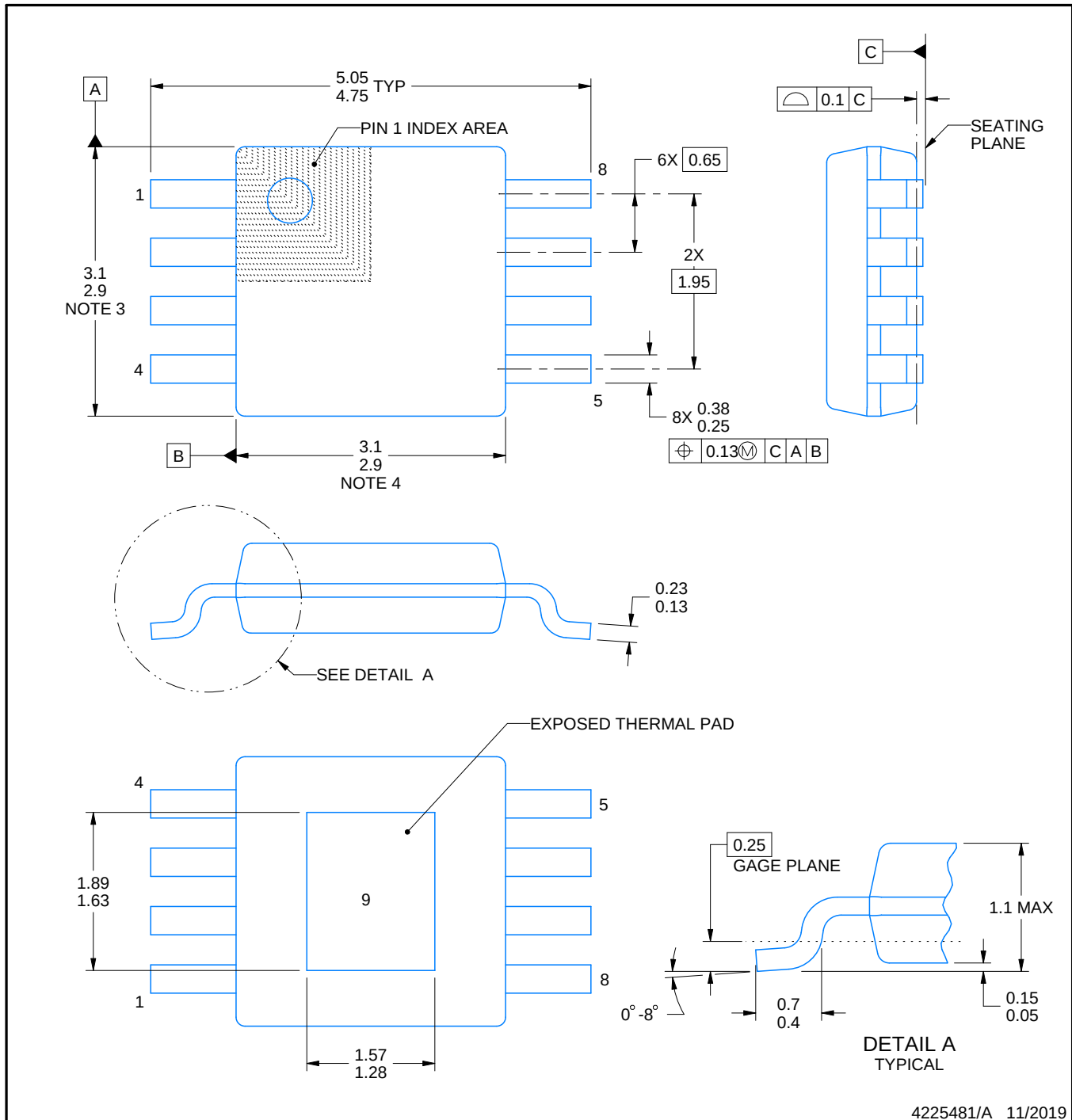
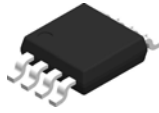
3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4225482/B



4225481/A 11/2019

NOTES:

PowerPAD is a trademark of Texas Instruments.

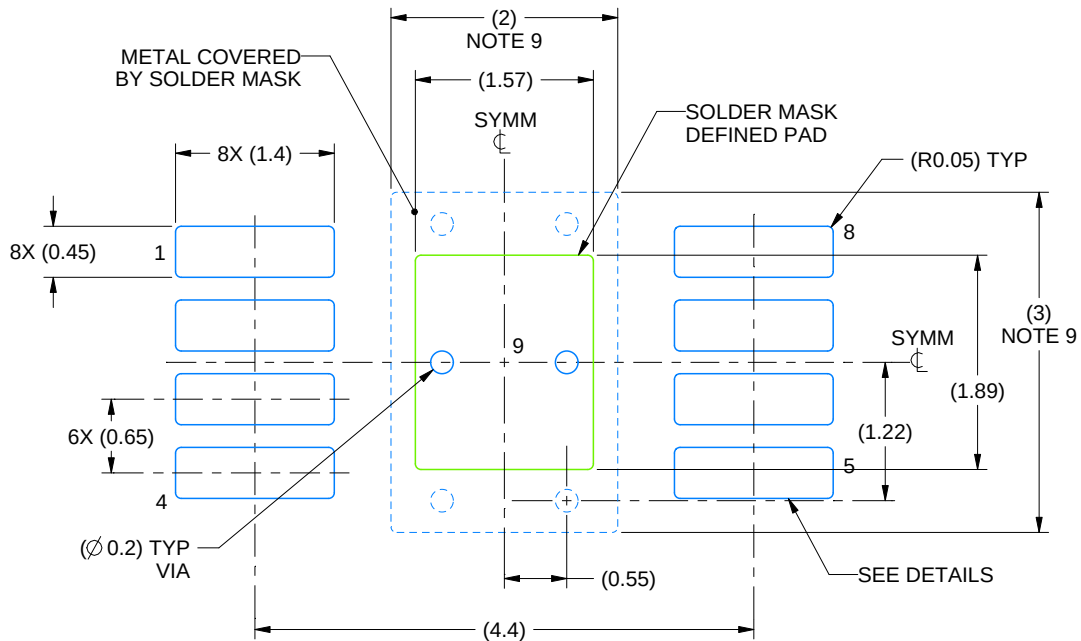
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

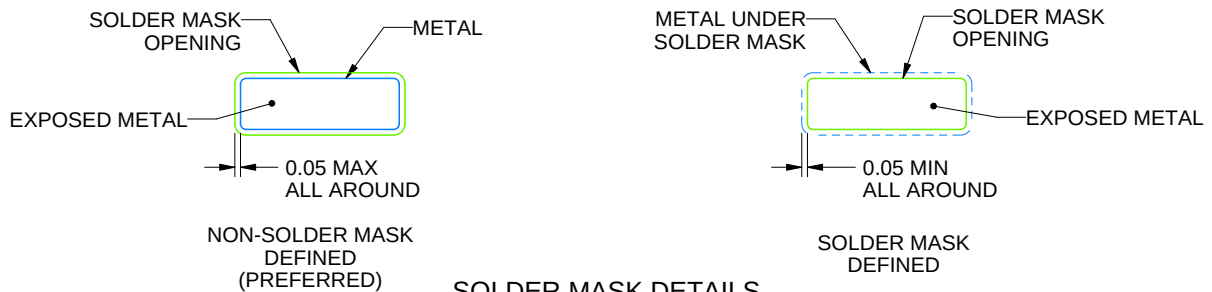
DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4225481/A 11/2019

NOTES: (continued)

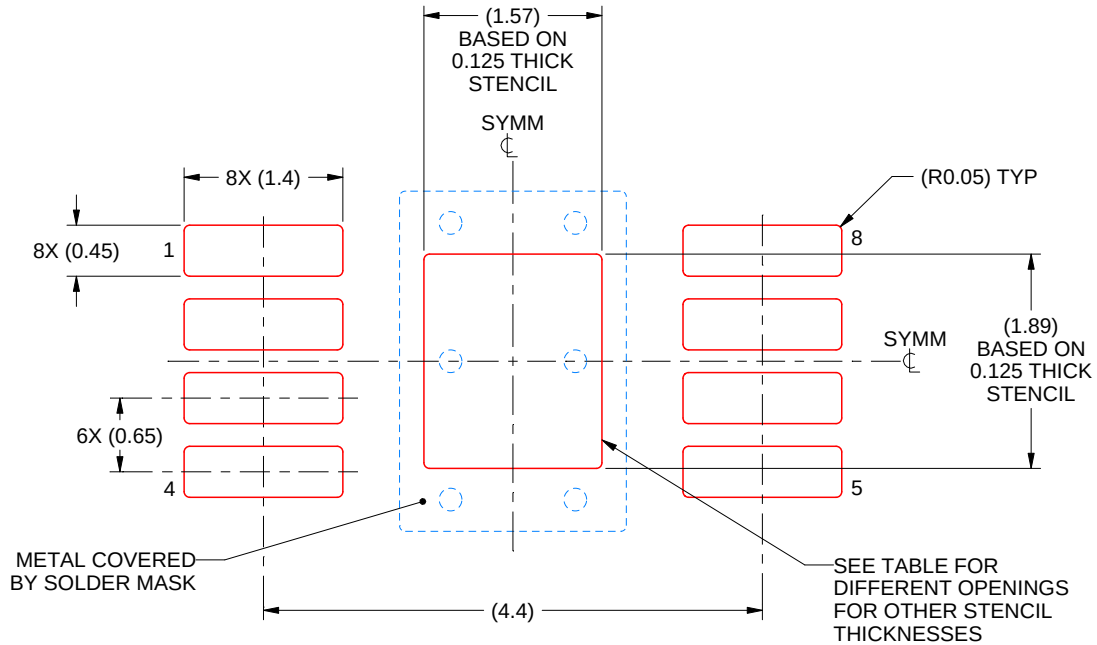
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



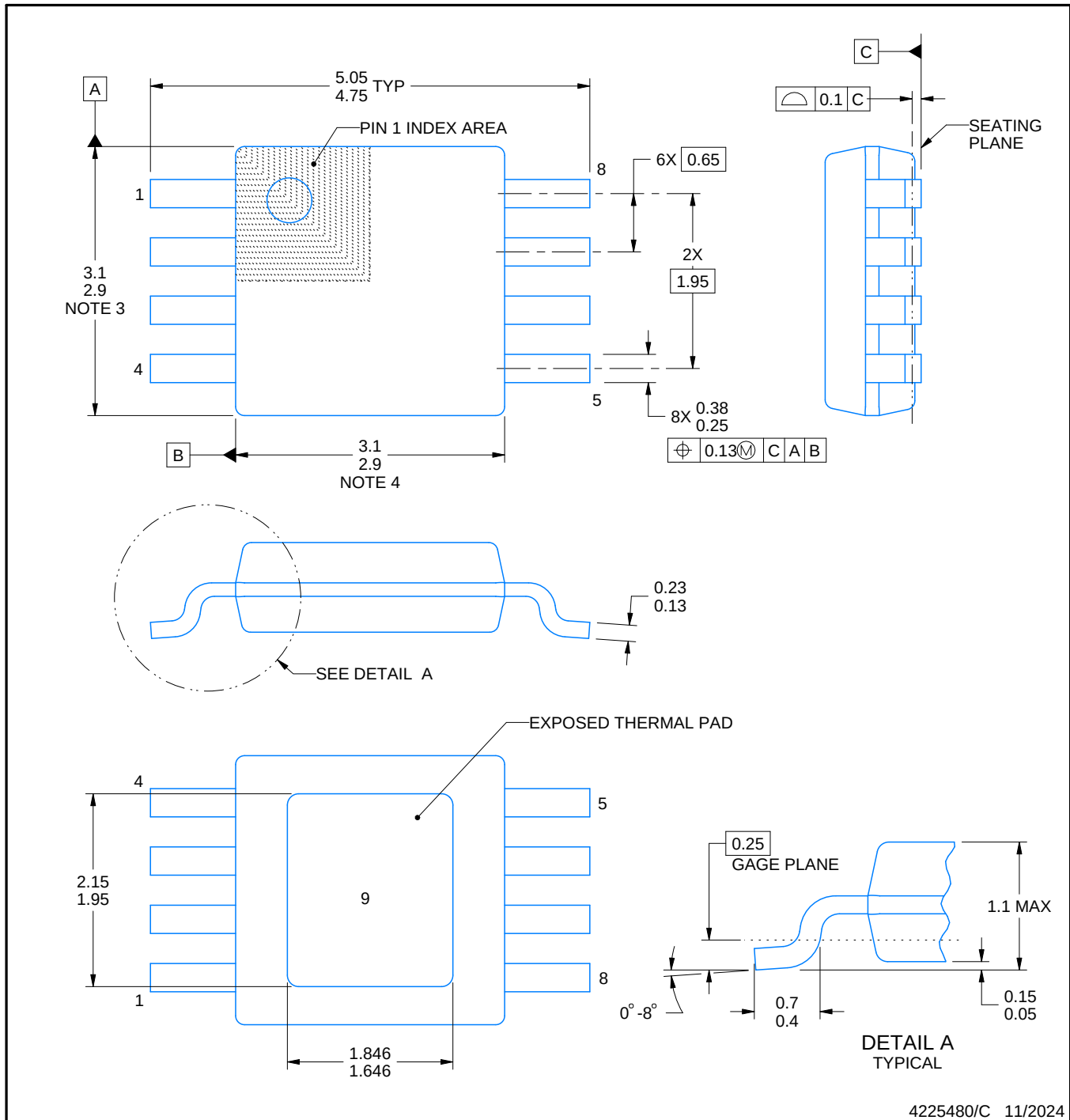
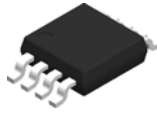
SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.76 X 2.11
0.125	1.57 X 1.89 (SHOWN)
0.15	1.43 X 1.73
0.175	1.33 X 1.60

4225481/A 11/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.



4225480/C 11/2024

NOTES:

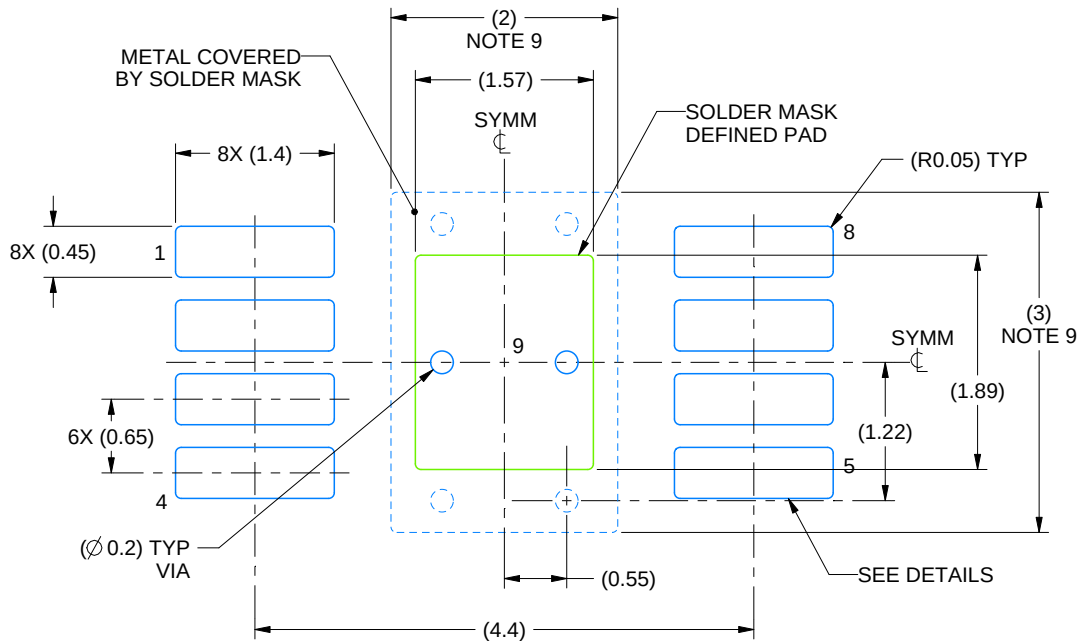
PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

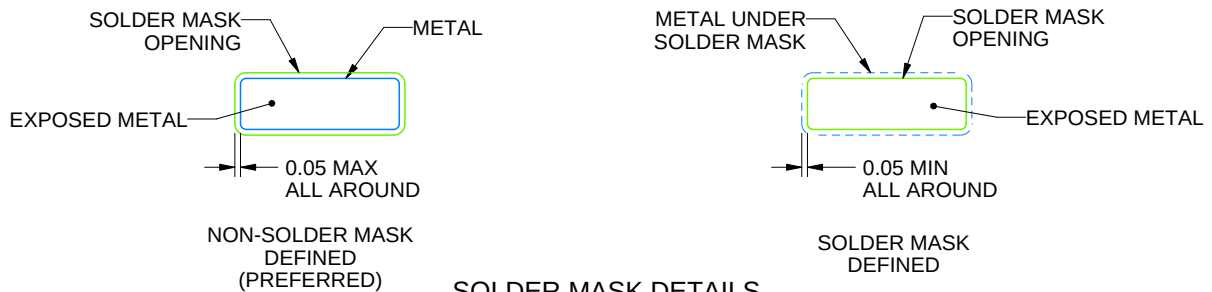
DGN0008G

PowerPAD™ HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4225480/C 11/2024

NOTES: (continued)

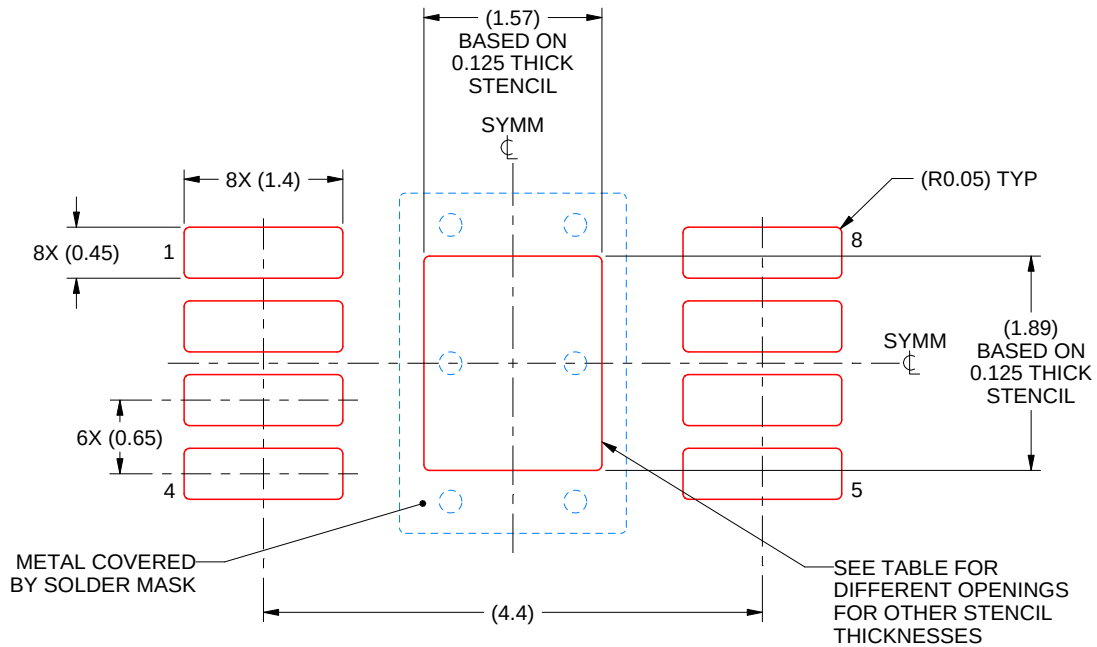
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGN0008G

PowerPAD™ HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



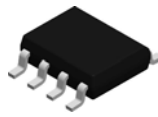
SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.76 X 2.11
0.125	1.57 X 1.89 (SHOWN)
0.15	1.43 X 1.73
0.175	1.33 X 1.60

4225480/C 11/2024

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

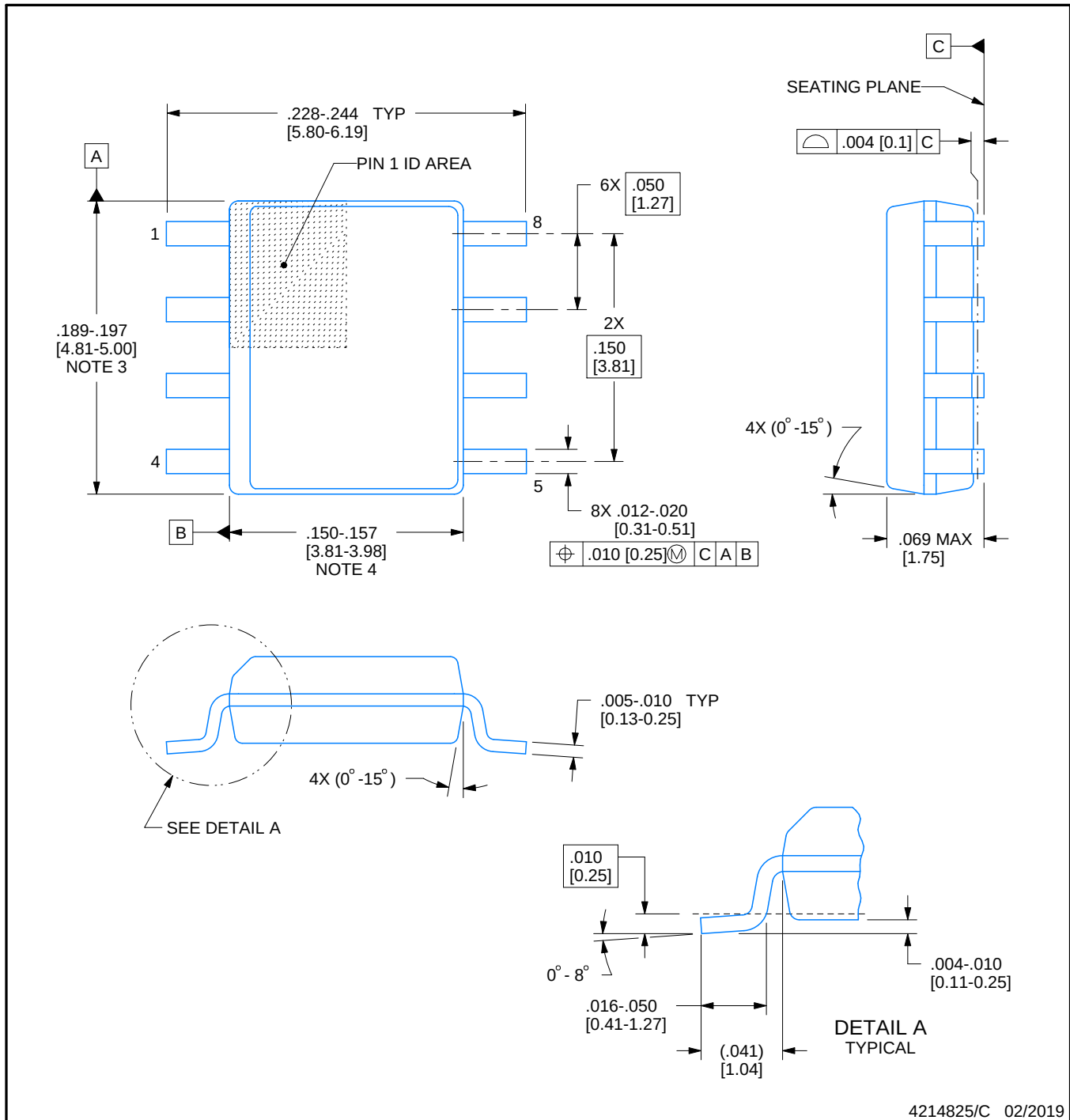


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

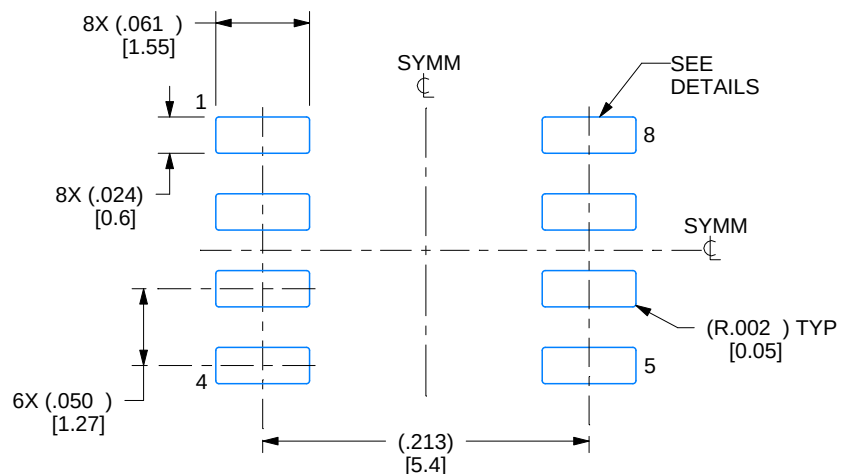
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

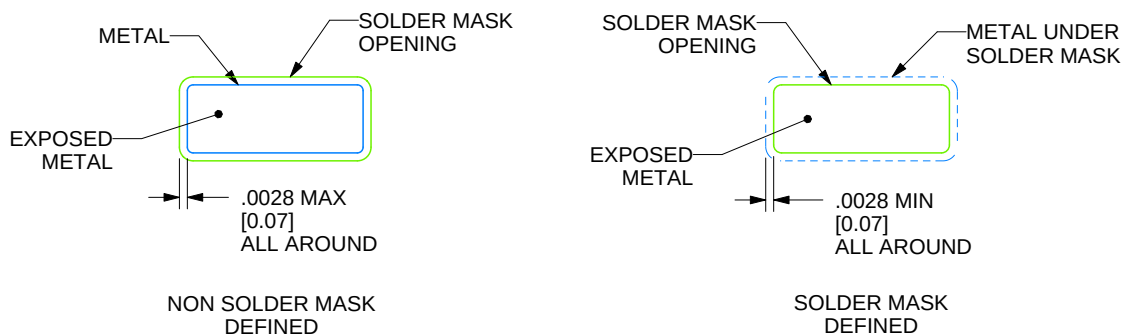
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

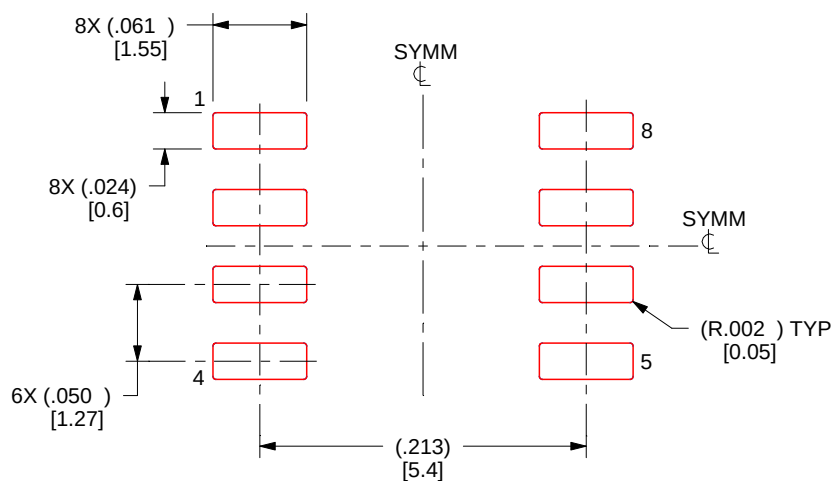
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

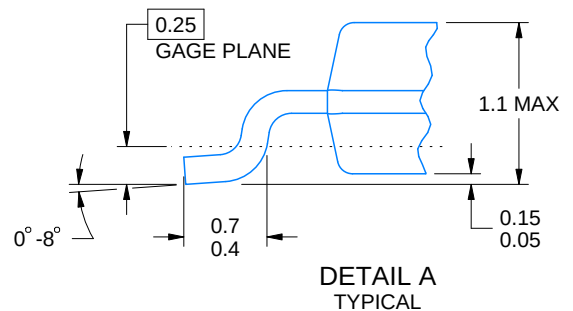
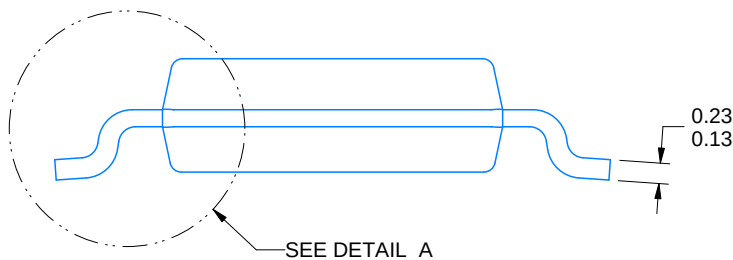
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



VSSOP - 1.1 mm max height

Technical drawing of a 6-pin connector. The drawing includes a top view and a side view. The top view shows a rectangular component with six pins on the right side. Dimensions include a total width of 5.05 (typical) and 4.75, a pin pitch of 1.95 (2X), and a pin width of 0.65 (6X). A circular feature is labeled "PIN 1 INDEX AREA". The side view shows the component's profile with a height of 3.1 (typical) and 2.9, and a pin height of 0.38 (typical) and 0.25. A "SEATING PLANE" is indicated. Callouts A, B, and C are present. A table of values is provided at the bottom right:

⊕	0.13	Ⓜ	C	A	B
---	------	---	---	---	---



PowerPAD is a trademark of Texas Instruments.

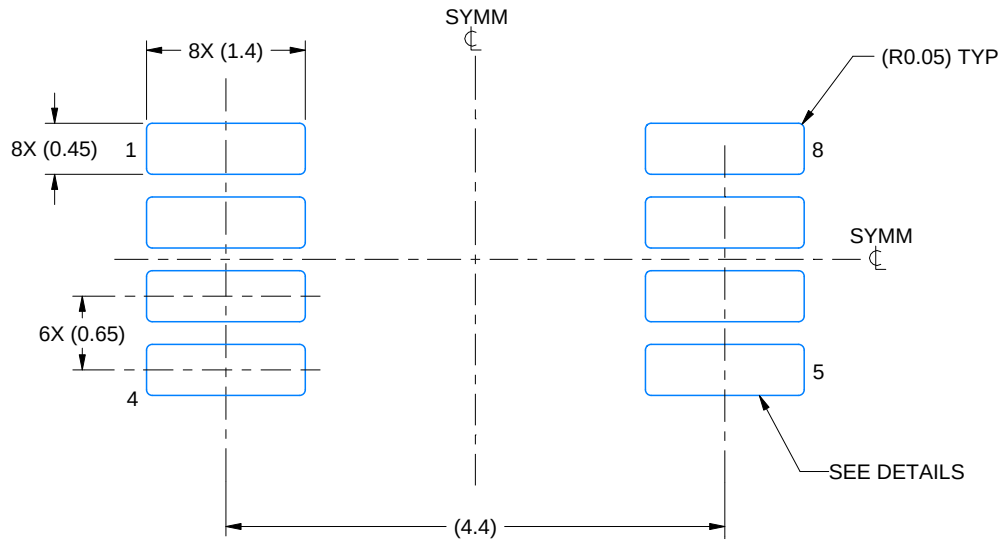
- 
- TEXAS
INSTRUMENTS
www.ti.com

EXAMPLE BOARD LAYOUT

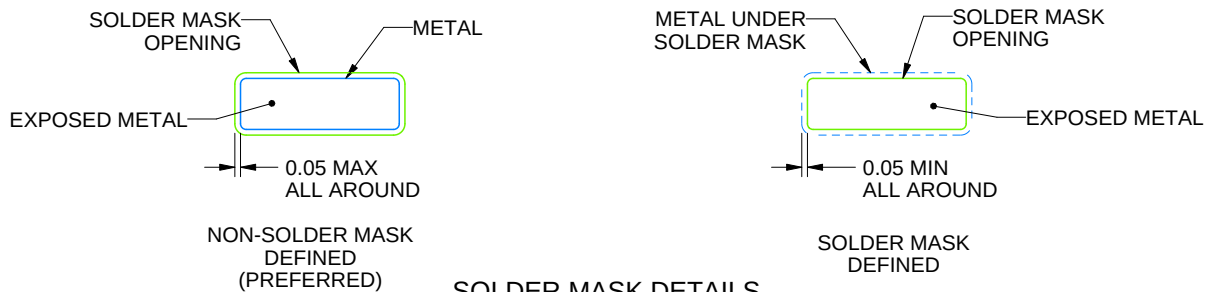
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

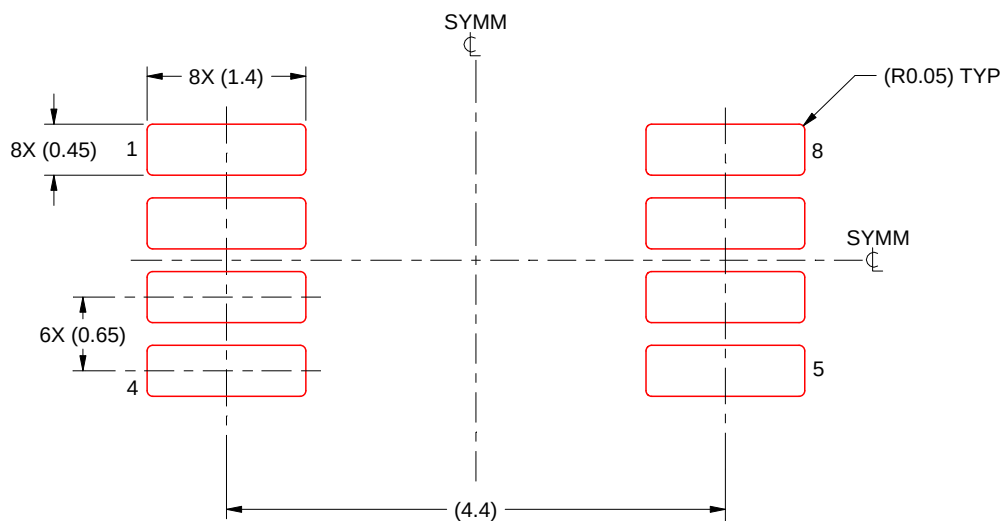
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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